

Summary of updates on the INTT geometry for Geant4

Genki Nukazuka (RBRC), INTT Bi-weekly meeting, 01/July/2020

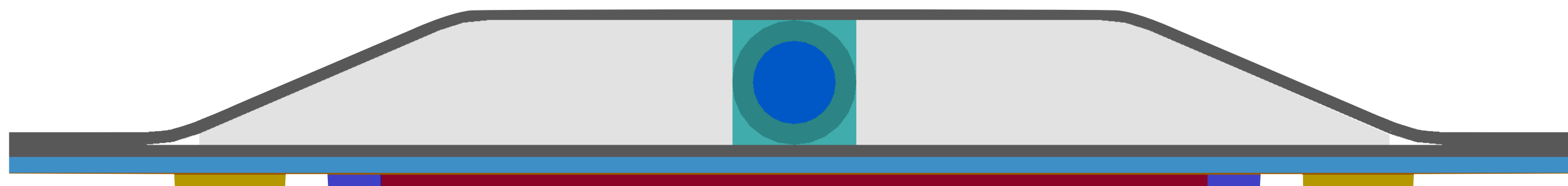
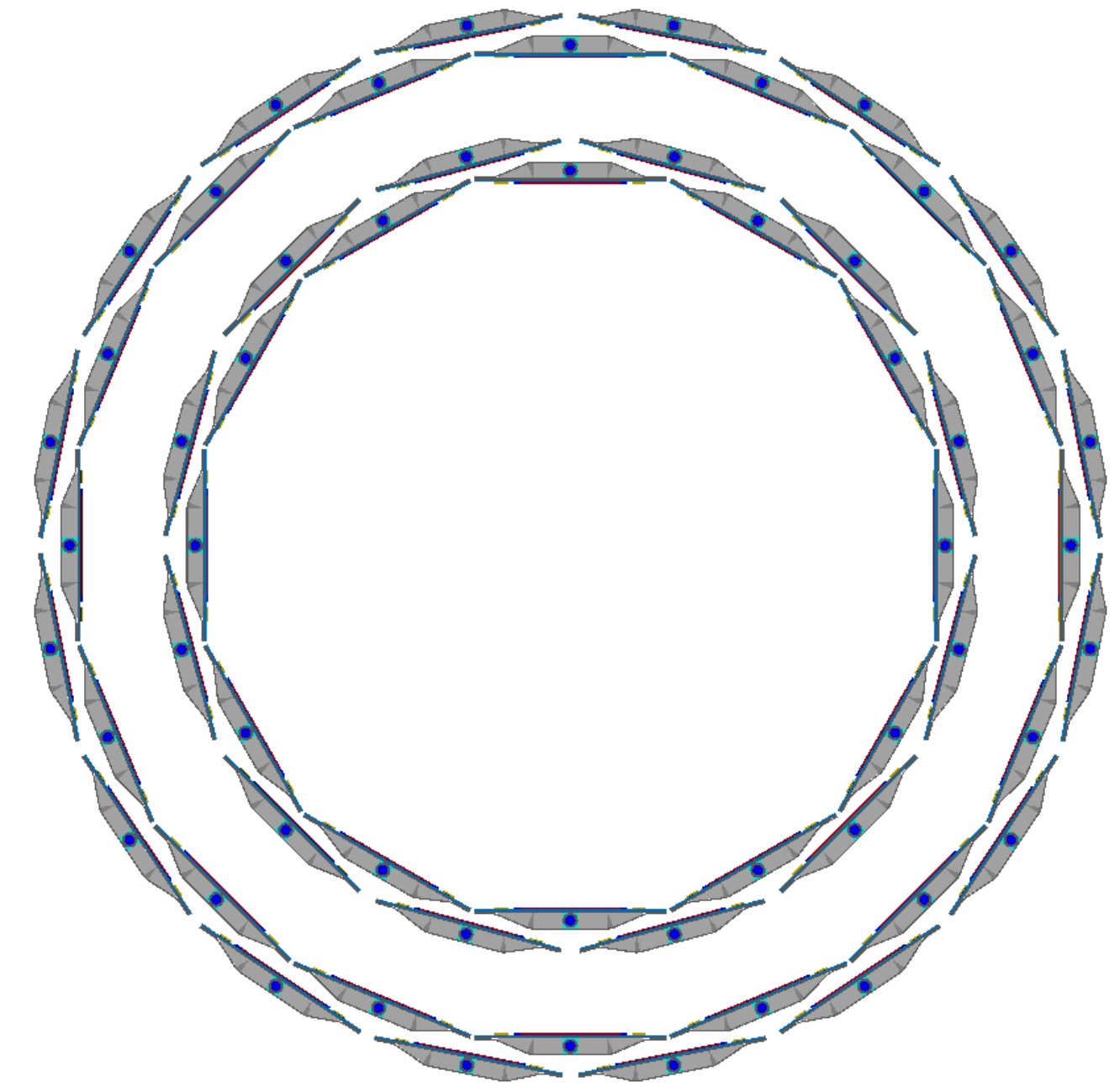
Updates

Ladder configuration

- A number of ladders in layers
- Distance of layers from the beam-axis

Ladder geometry

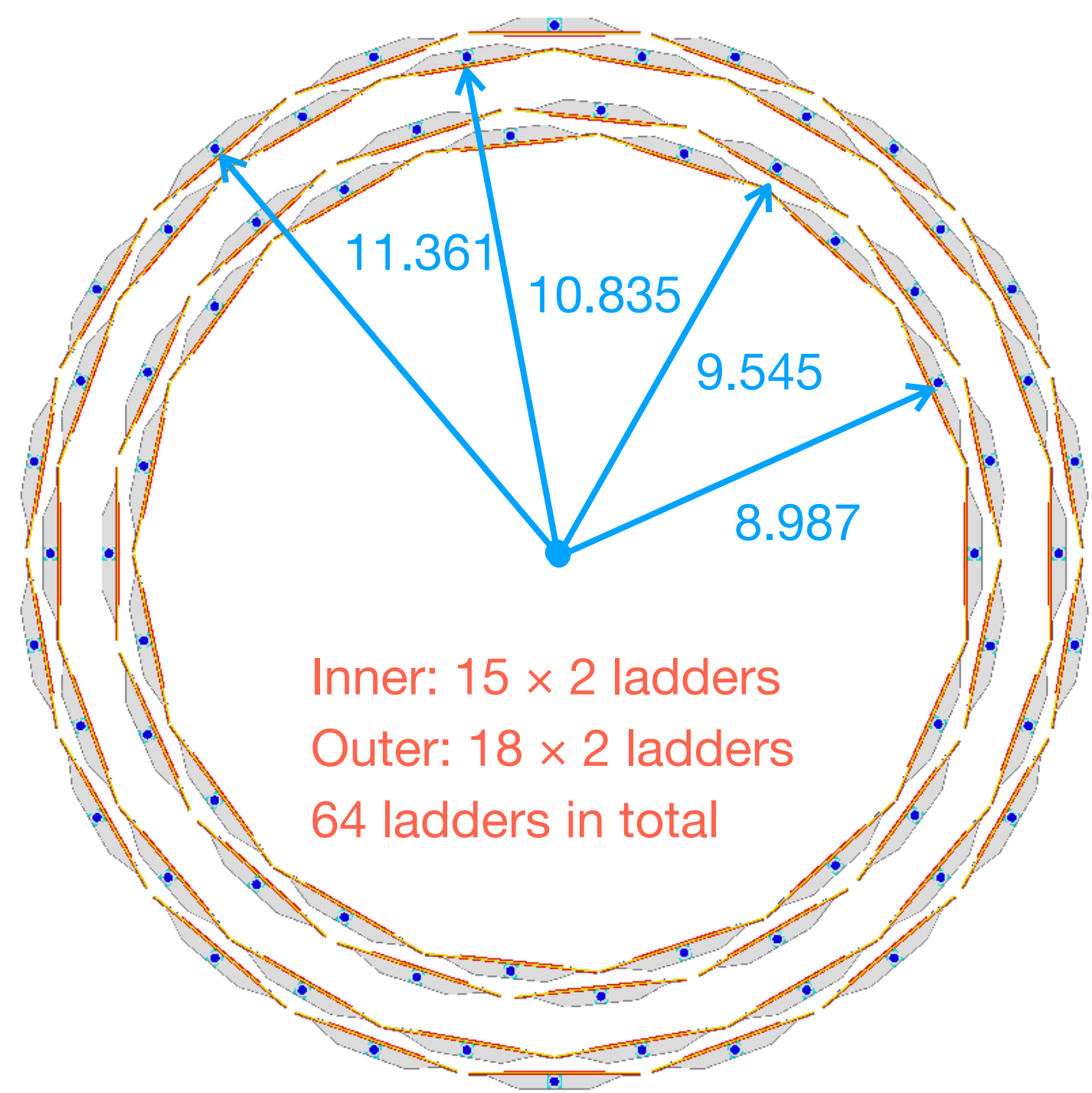
- Replacement of PGS to the flat CFRP plate
- Change of thickness of the formed and flat CFRP plates
- Change of thickness of the copper layer in HDI
- Addition of the silver epoxy glue for the silicon sensor and FPHX chips



Ladder configuration

Model in the current repository

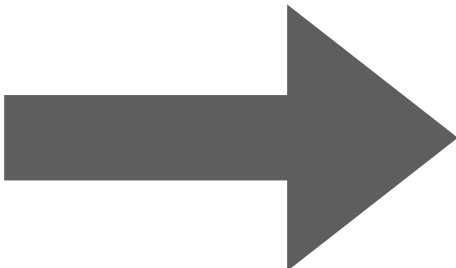
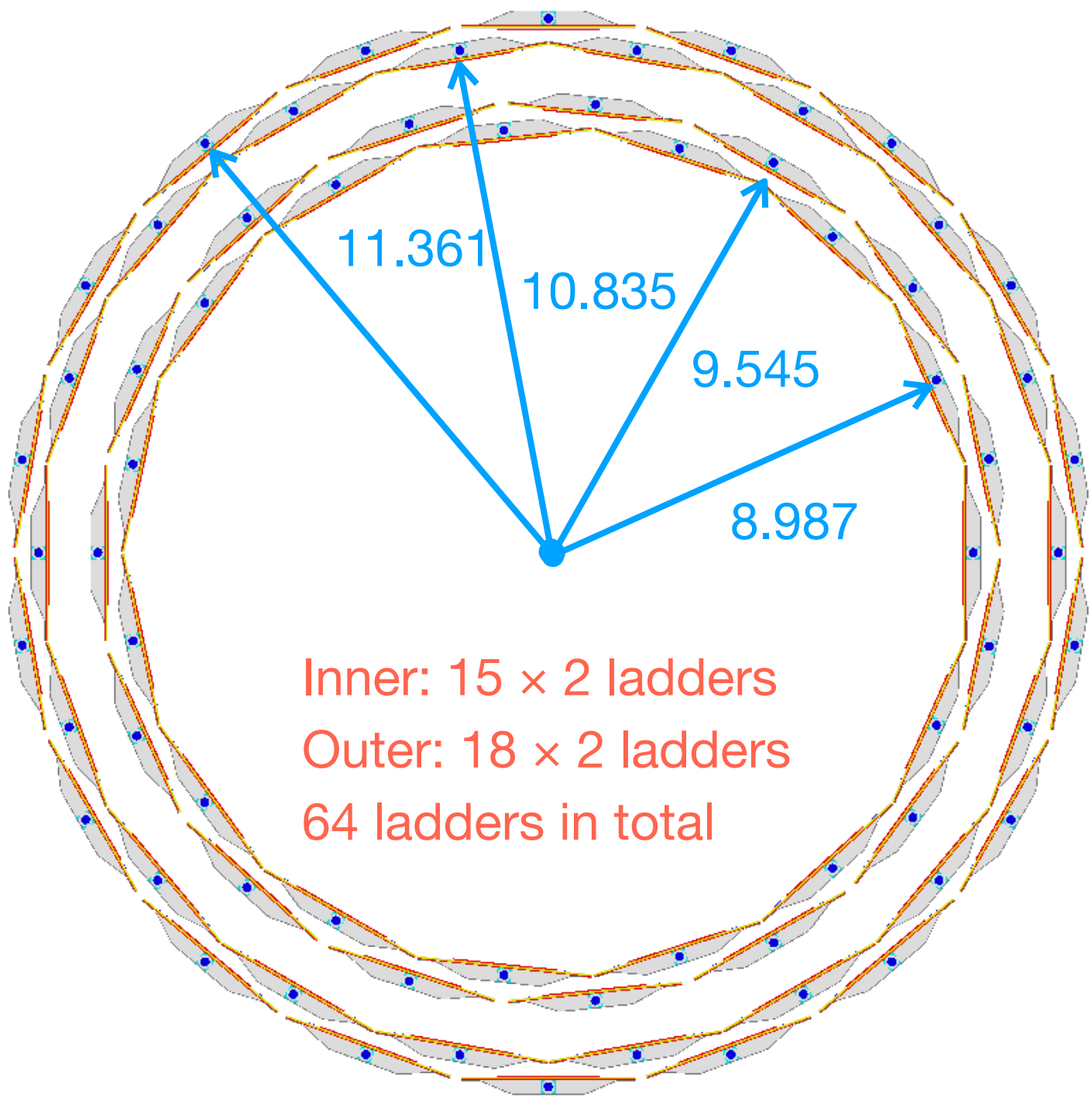
Layer	#ladder	Distance from the beam-axis (cm)
1a (Innermost)	15	8.987
1b (2nd innermost)	15	9.545
2a (2nd outermost)	18	10.835
2b (Outermost)	18	11.361



Ladder configuration

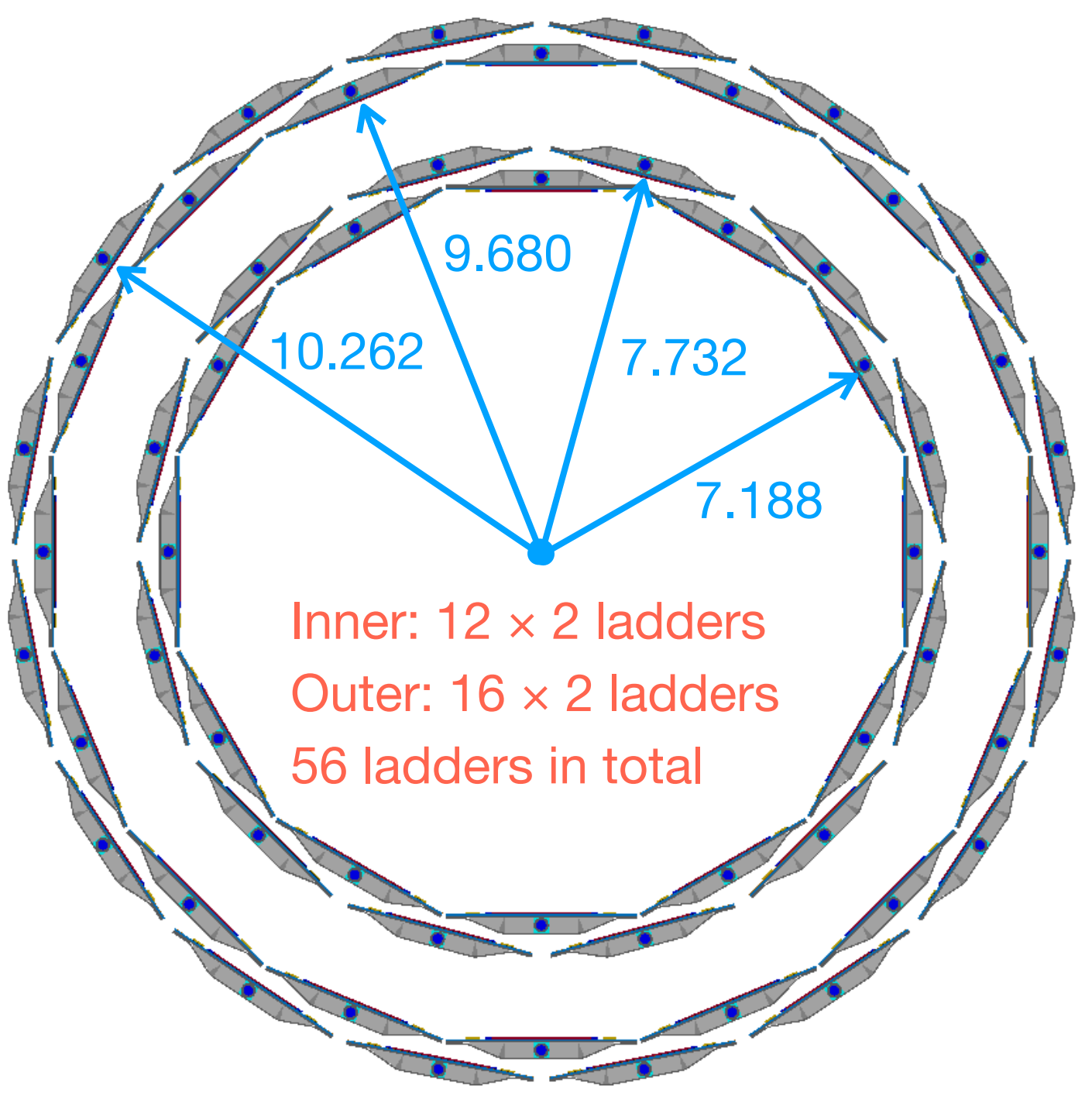
Model in the current repository

Layer	#ladder	Distance from the beam-axis (cm)
1a (Innermost)	15	8.987
1b (2nd innermost)	15	9.545
2a (2nd outermost)	18	10.835
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Updated model

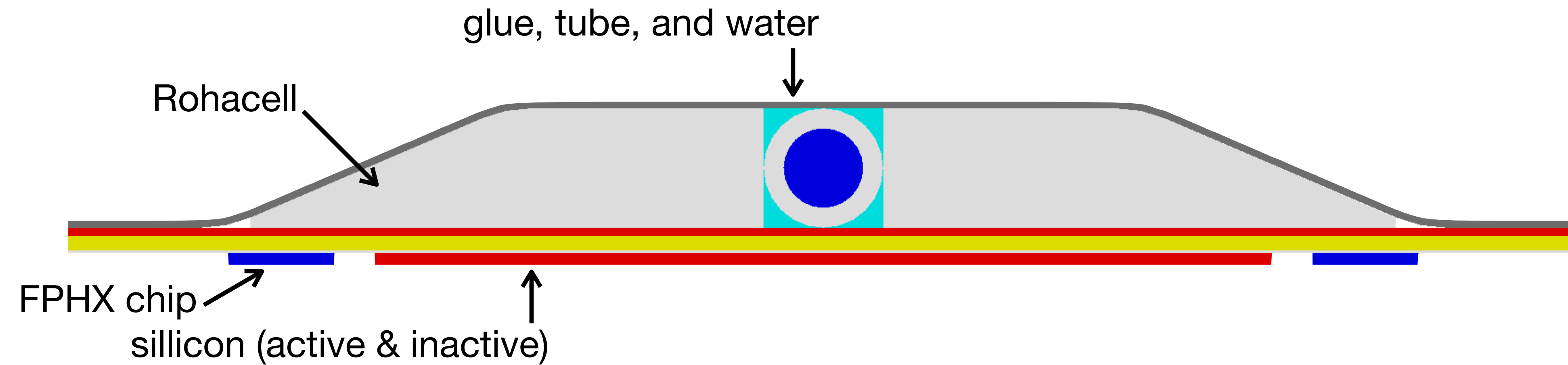
Layer	#ladder	Distance from the beam-axis (cm)
1a (Innermost)	12	7.188
1b (2nd innermost)	12	7.732
2a (2nd outermost)	16	9.680
2b (Outermost)	16	10.262



(cm)

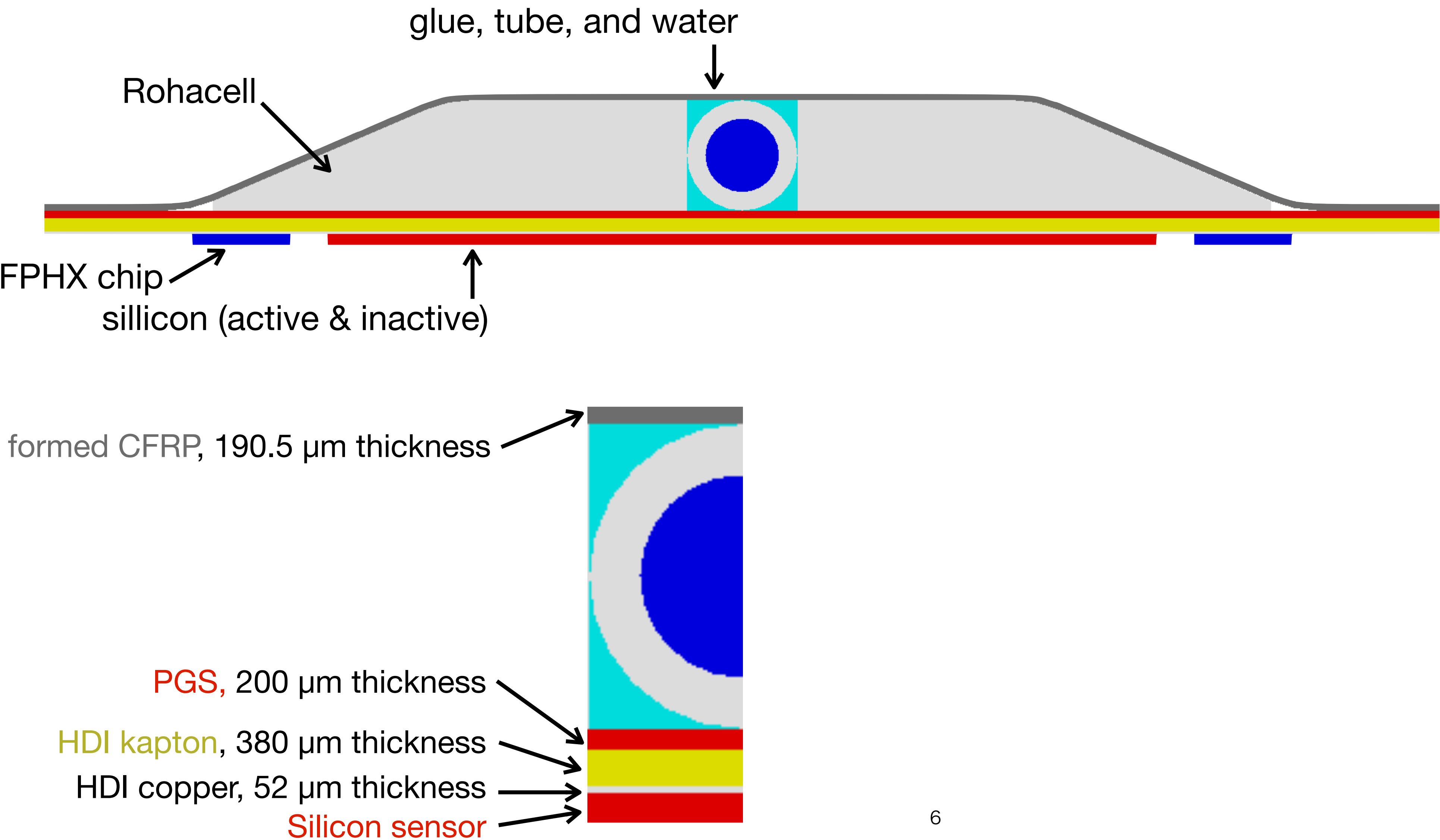
Geometry of the ladder

Model in the current repository



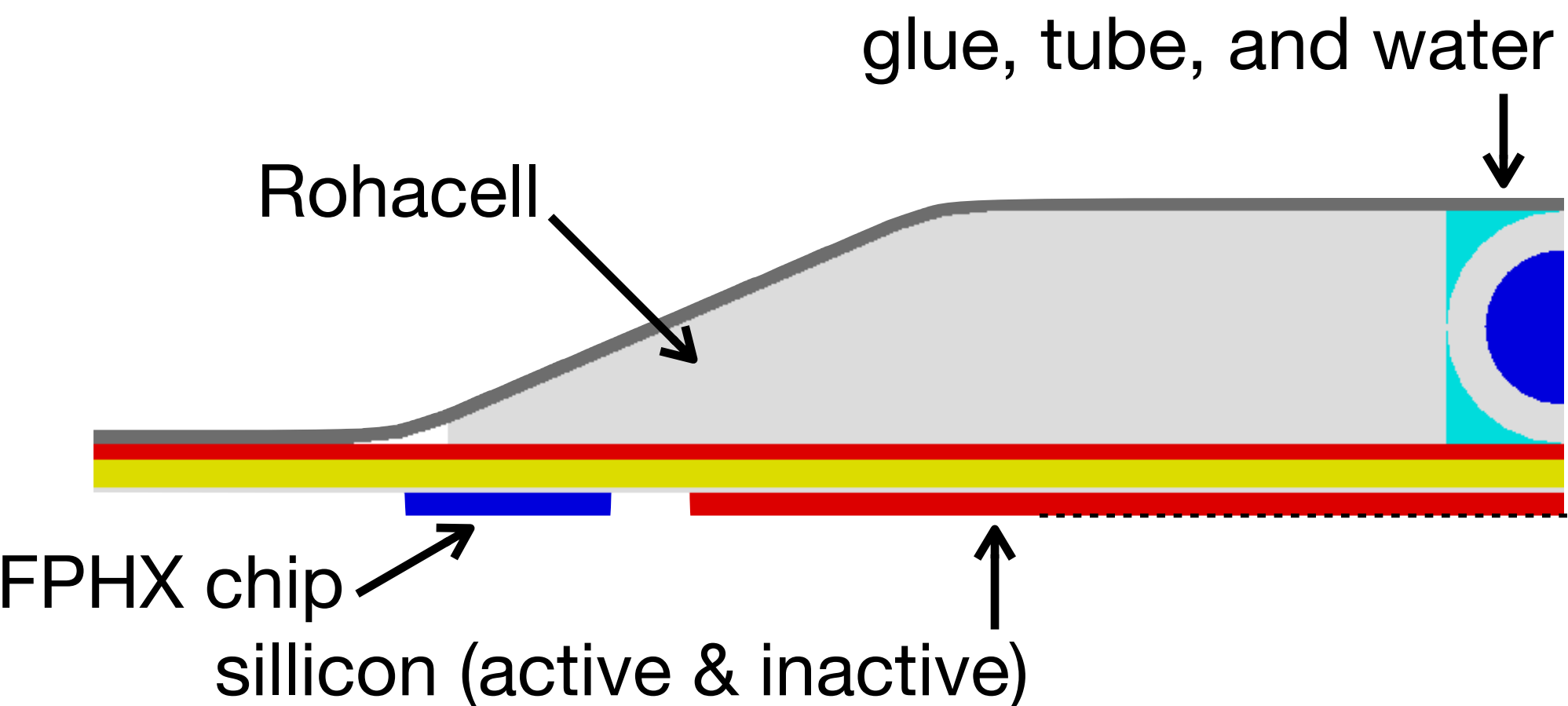
Geometry of the ladder

Model in the current repository

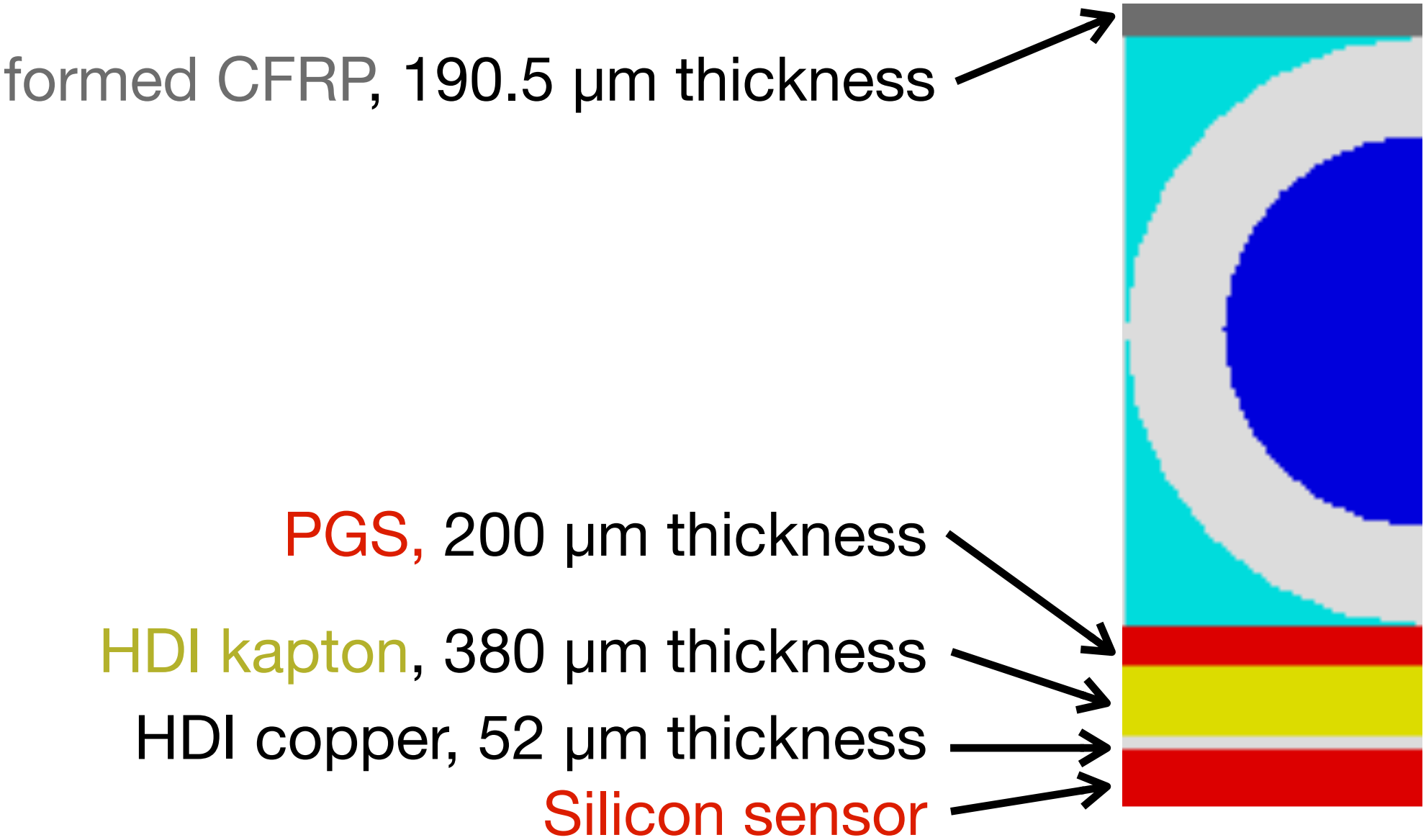
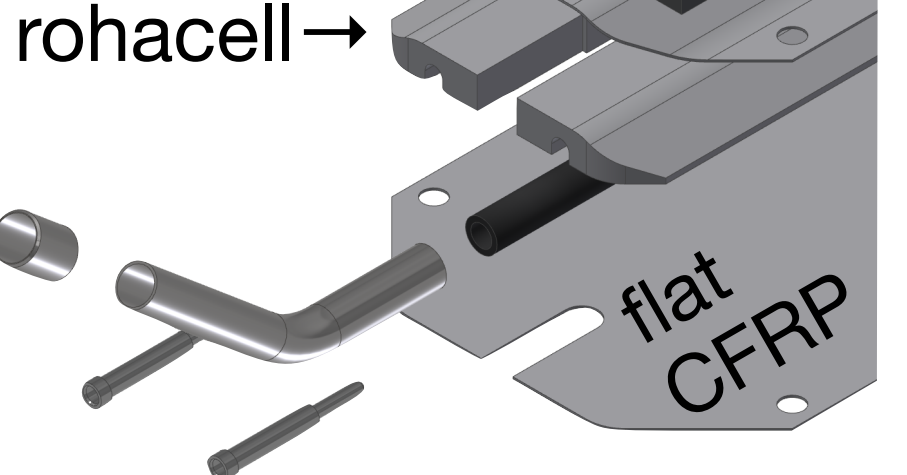
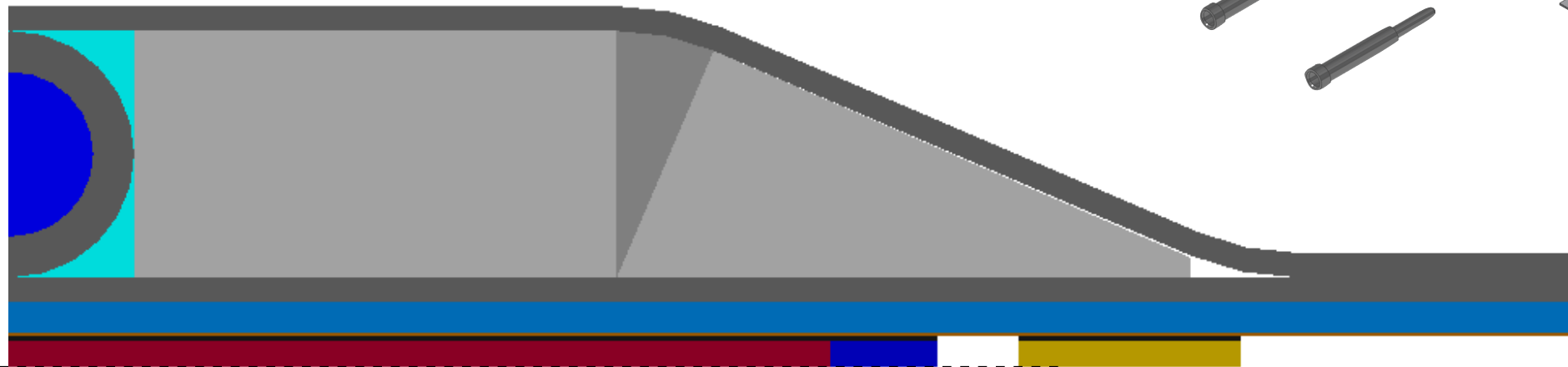


Geometry of the ladder

Model in the current repository

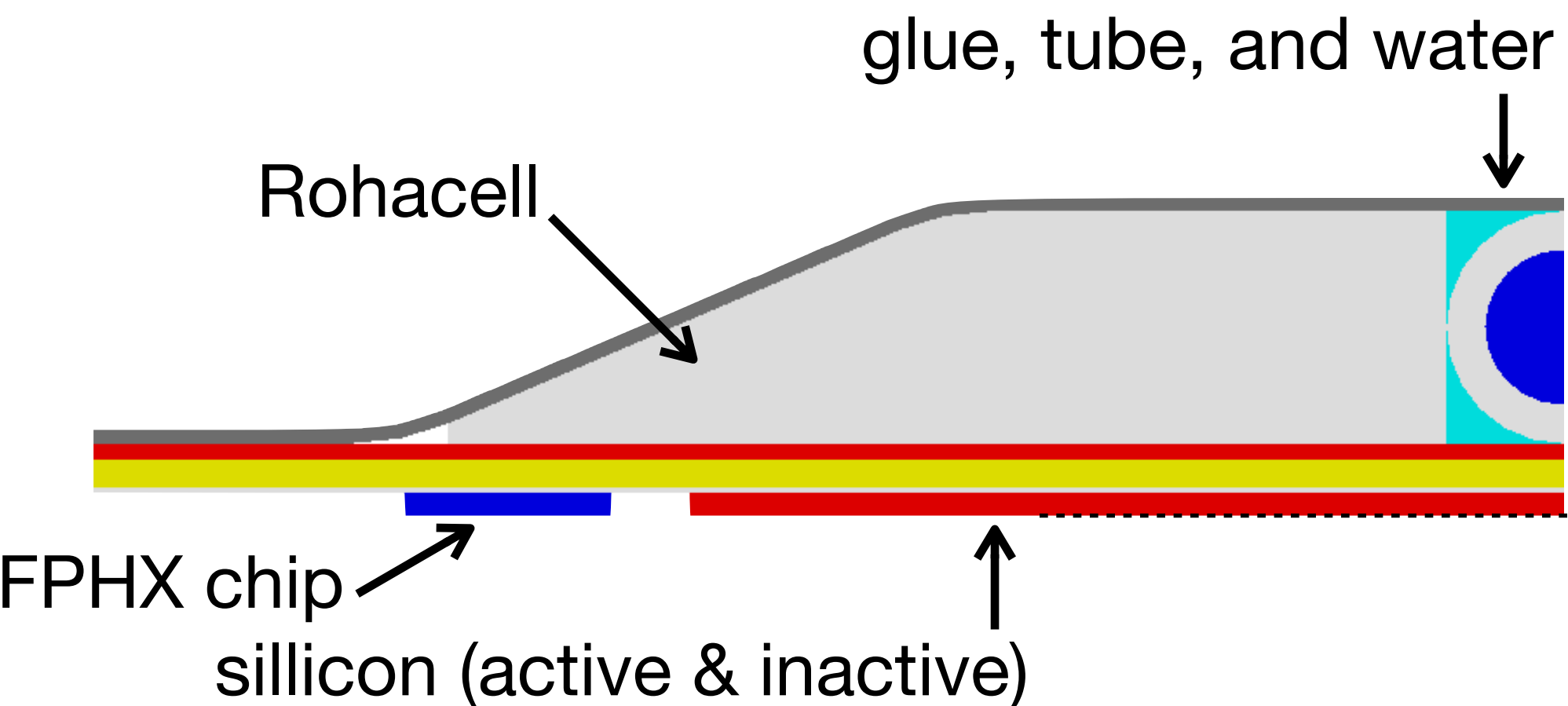


Updated model

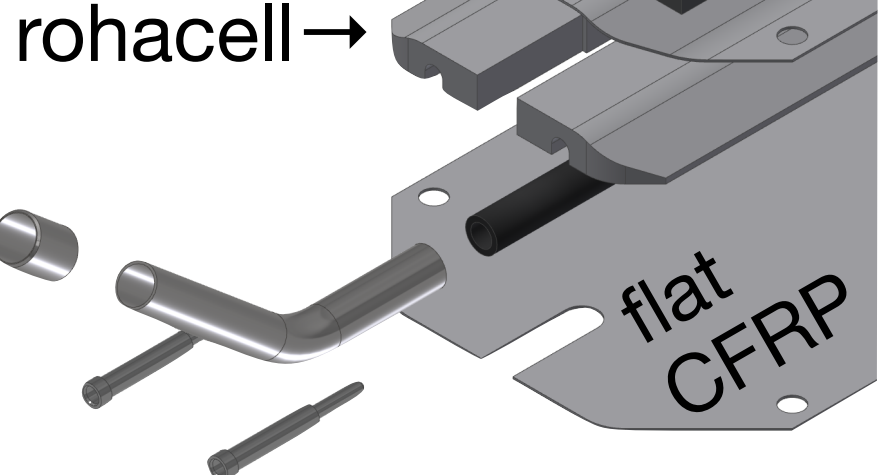
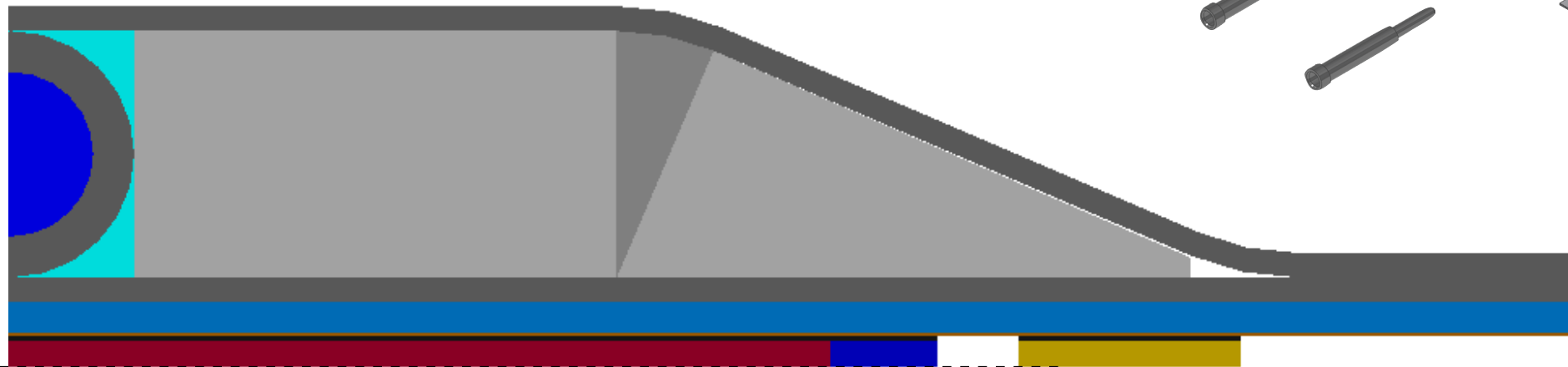


Geometry of the ladder

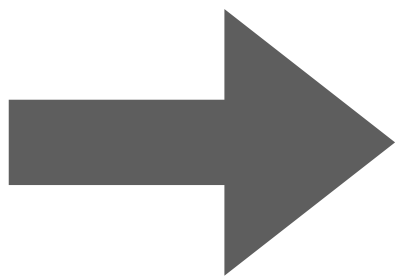
Model in the current repository



Updated model



formed CFRP, 190.5 μm thickness



formed CFRP, 300 μm thickness



flat CFRP plate, 300 μm thickness

HDI kapton, 380 μm thickness

HDI copper, 37.6 μm thickness

Glue (silver), 50 μm thickness

Silicon sensor

The silver epoxy glue for FPHX chips

Provided information by Henkel: Specific gravity is 3.2

	Specific gravity	Ratio	Ratio (average)
Glue	3.2		
Ag	10.5	0.198 - 0.223	0.21
Epoxy	1.1 - 1.4	0.777 - 0.802	0.79

Technical Data Sheet

LOCTITE ABLESTIK 2902

October 2014

PRODUCT DESCRIPTION

LOCTITE ABLESTIK 2902 provides the following product characteristics:

Technology	Epoxy
Appearance	Silver
Filler Type	Silver
Cure	Room Temperature or Heat Cure
Components	Two component - requires mixing
Product Benefits	<ul style="list-style-type: none">Electrically conductiveThermally conductiveSolvent-freeHigh adhesionTwo componentRoom temperature cureGood adhesion to a variety of substrates
Mix Ratio, by weight - Resin : Hardener	100 : 6
Typical Assembly Applications	Electrical modules, Printed circuitry, Wave guides, Flat cables, High frequency shields and Cold solder
Operating Temperature	-60 to 110 °C
Application	Bonding, Sealing or Repair
Surfaces	Ceramics, Many metals, Glass and Plastic laminates

LOCTITE ABLESTIK 2902 is designed for electronic bonding and sealing applications that require a combination of good mechanical and electrical properties.

LOCTITE ABLESTIK 2902 passes NASA outgassing standards.

ISO-10993-5

LOCTITE ABLESTIK 2902 was tested to and passed the requirements of ISO 10993-5 for Cytotoxicity.

TYPICAL PROPERTIES OF UNCURED MATERIAL

Mixed Viscosity, mPa·s (cP) :	
cp #52, 10 rpm	20,000
Specific Gravity, mixed	3.2
Pot life , minutes	60
Flash Point - See SDS	

TYPICAL CURING PERFORMANCE

Cure Schedule

24 hours @ 25°C or
1 to 4 hours @ 65°C

The above cure profile is a guideline recommendation. Cure conditions (time and temperature) may be based on customers' experience and their application requirements, as well as customer curing equipment, oven loading and oven temperatures.

TYPICAL PROPERTIES OF CURED MATERIAL

Physical Properties

Coefficient of Thermal Expansion, cm/cm°C	4.9×10 ⁻⁶
Glass Transition Temperature (Tg), °C	52
Thermal Conductivity , W/(m-K)	2.99×10 ⁻²⁰
Hardness, Shore D	80

Electrical Properties

Volume Resistivity, ohms-cm:

1 hour @ 110°C	0.0006
15 minutes @ 150°C	0.0005
2 hours @ 65°C	0.0009
24 hours @ 25°C	0.001
5 minutes @ 160°C	0.0003

Outgassing Properties

Total Mass Loss, %	0.64
Collected Volatile Condensable Material, %	0.05

TYPICAL PERFORMANCE OF CURED MATERIAL

Shear Strength

Lap Shear Strength :

Aluminum:

Cured @ 110 °C for 1 hour	N/mm ² 11 (psi) (1,600)
Cured @ 150 °C for 15 minutes	N/mm ² 11 (psi) (1,600)
Cured @ 65 °C for 2 hours	N/mm ² 7 (psi) (1,000)
Cured @ 25 °C for 24 hours	N/mm ² 5 (psi) (700)

GENERAL INFORMATION

For safe handling information on this product, consult the Material Safety Data Sheet, (MSDS).

DIRECTIONS FOR USE

- Carefully clean and dry all surfaces to be bonded.
- Remove clamp and thoroughly mix the LOCTITE ABLESTIK 2902 epoxy adhesive system components in the handy BIPAX mixing-dispenser package until color is uniform throughout.
- Apply this completely mixed adhesive to the prepared surfaces, and gently press these surfaces together. Contact pressure is adequate for strong, reliable bonds; however, maintain contact until adhesive is completely cured.
- Some separation of components is common during shipping and storage. For this reason, it is recommended that the contents of the shipping container be thoroughly mixed prior to use.
- Some ingredients in this formulation provided in BIPAX, TRA-PAX and bulk packaging may crystallize when subjected to low temperature storage. A gentle warming cycle of 52°C for 30 minutes prior to mixing components may be necessary. Crystallized epoxy components do not react as well as liquid components and should be redissolved prior to use for best results.

already written,
actually...

The silver epoxy glue for FPHX chips

Provided information by Henkel: Specific gravity is 3.2

	Specific gravity	Ratio	Ratio (average)
Glue	3.2		
Ag	10.5	0.198 - 0.223	0.21
Epoxy	1.1 - 1.4	0.777 - 0.802	0.79

Definition of the material in Geant4 to be added:

```
g4main/PHG4Reco.cc  
L876
```

```
//from http://www.physi.uni-heidelberg.de/~adler/TRD/TRDunterlagen/RadiatonLength/tgc2.htm  
//Epoxy (for FR4 )  
//density = 1.2*g/cm3;  
G4Material *Epoxy = new G4Material("Epoxy", 1.2 * g / cm3, ncomponents = 2);  
Epoxy->AddElement(G4Element::GetElement("H"), natoms = 2);  
Epoxy->AddElement(G4Element::GetElement("C"), natoms = 2);
```

Epoxy for
something else

```
// Silver epoxy glue LOCTITE ABLESTIK 2902 for the silicon sensors and FPHX chips of INTT  
G4Material *SilverEpoxyGlue_INTT = new G4Material("SilverEpoxyGlue_INTT", density = 3.2 * g / cm3, ncomponents = 2);  
SilverEpoxyGlue_INTT->AddMaterial(Epoxy, fractionmass = 0.79);  
SilverEpoxyGlue_INTT->AddMaterial(G4Material::GetMaterial("G4_Ag"), fractionmass = 0.21);
```

The silver epoxy glue for FPHX chips

Provided information by Henkel: Specific gravity is 3.2

	Specific gravity	Ratio	Ratio (average)
Glue	3.2		
Ag	10.5	0.198 - 0.223	0.21
Epoxy	1.1 - 1.4	0.777 - 0.802	0.79

Amount of material in the glue with respect to the copper in HDI:

	Material	Density (g/cc)	Effective thickness (µm)	Amount ratio wrt Cu of HDI
Cu of HDI	Cu	8.94	37.6	1.00
Glue, Ag	Ag	10.49	10.5	0.33
Glue, epoxy	H, C, O	1.1 - 1.4	39.5	0.15

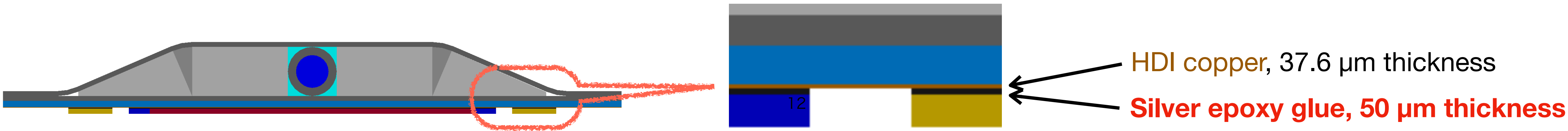


The silver epoxy glue for FPHX chips

The effective thickness 37.6 μm of the copper in HDI is input to Geant4 while the actual thickness is 52 μm . Should the glue thickness is given in the same way?

Amount of material in the glue with respect to the copper in HDI:

	Material	Density (g/cc)	Effective thickness (μm)	Amount ratio wrt Cu of HDI
Cu of HDI	Cu	8.94	37.6	1.00
Glue, Ag	Ag	10.49	10.5	0.33
Glue, epoxy	H, C, O	1.1 - 1.4	39.5	0.15



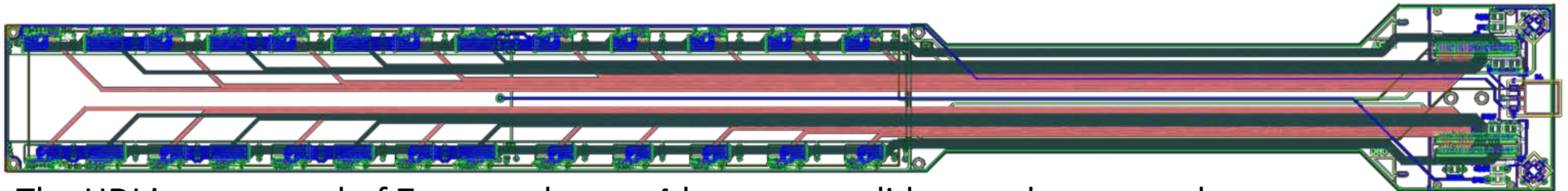
Radiation Length of INTT Ladder

Material	Thickness [μm]	X/X_0
Silicon	320	0.30%
HDI	473	0.40%
Stave	3620	0.40%
Total	4413	1.10%

HDI Material	Thickness [μm]	X/X_0
Copper*	38	0.26%
Polyimide	380	0.14%
Total**	432	0.40%

*Copper thickness is not physical thickness, but average thickness.

**Total thickness is not 473 μm , because of copper average thickness.



The HDI is composed of 7 copper layers. 4 layers are solid ground or power layers. The remaining 3 layers are signal line layers containing a few percent of solid copper per layer. All components are averaged over the area of the stave in the active region.

Stave Average Radiation Length

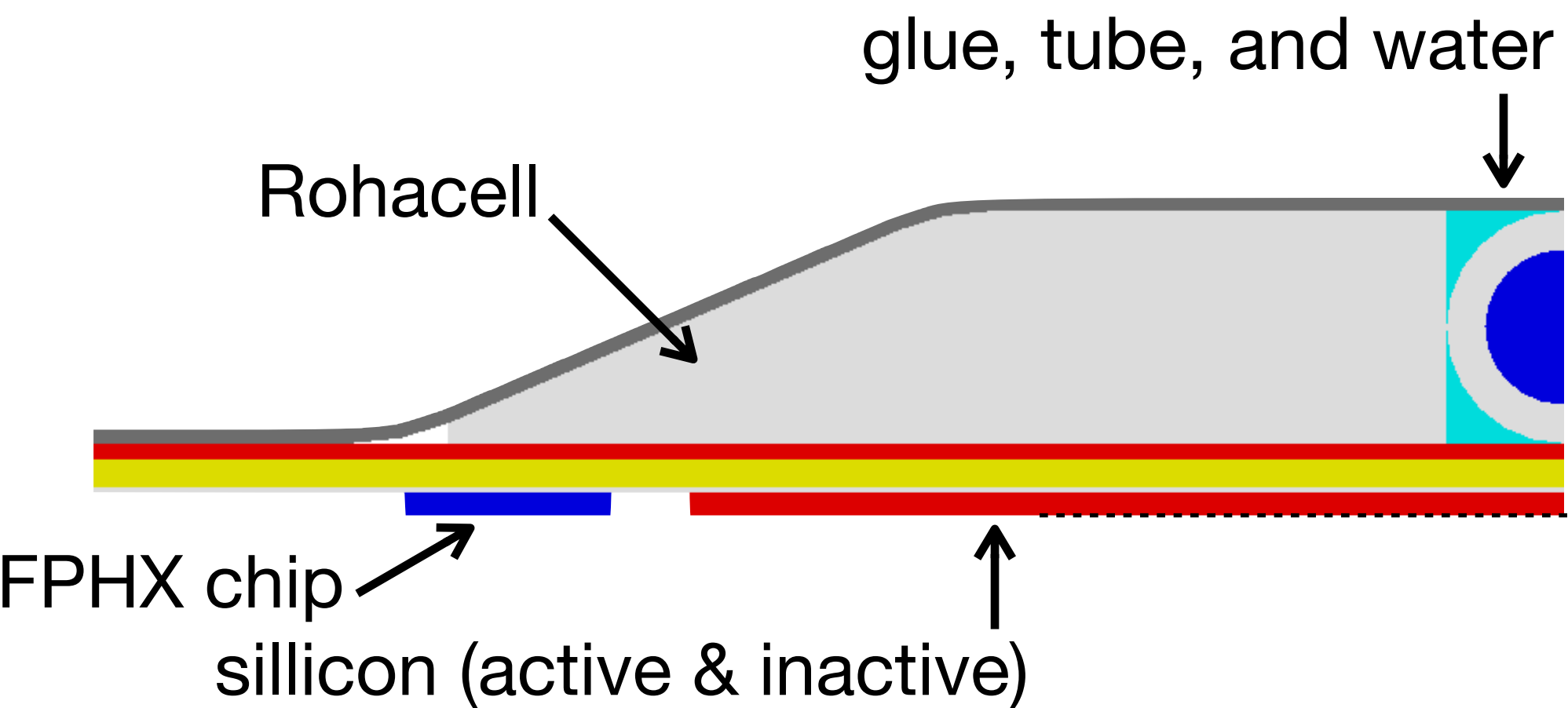


Stave	Equivalent Thickness (mm)	Radiation Length (mm)	X/X0 *100
CFC Flat	0.3300	256.4122	0.1287
CFC Formed	0.3411	256.4122	0.1330
CFC Tube	0.1033	282.2909	0.0366
Foam	1.4740	3771.3741	0.0391
Epoxy	0.1016	298.7463	0.0340
Water	0.0826	356.7854	0.0231
		Total	0.3946

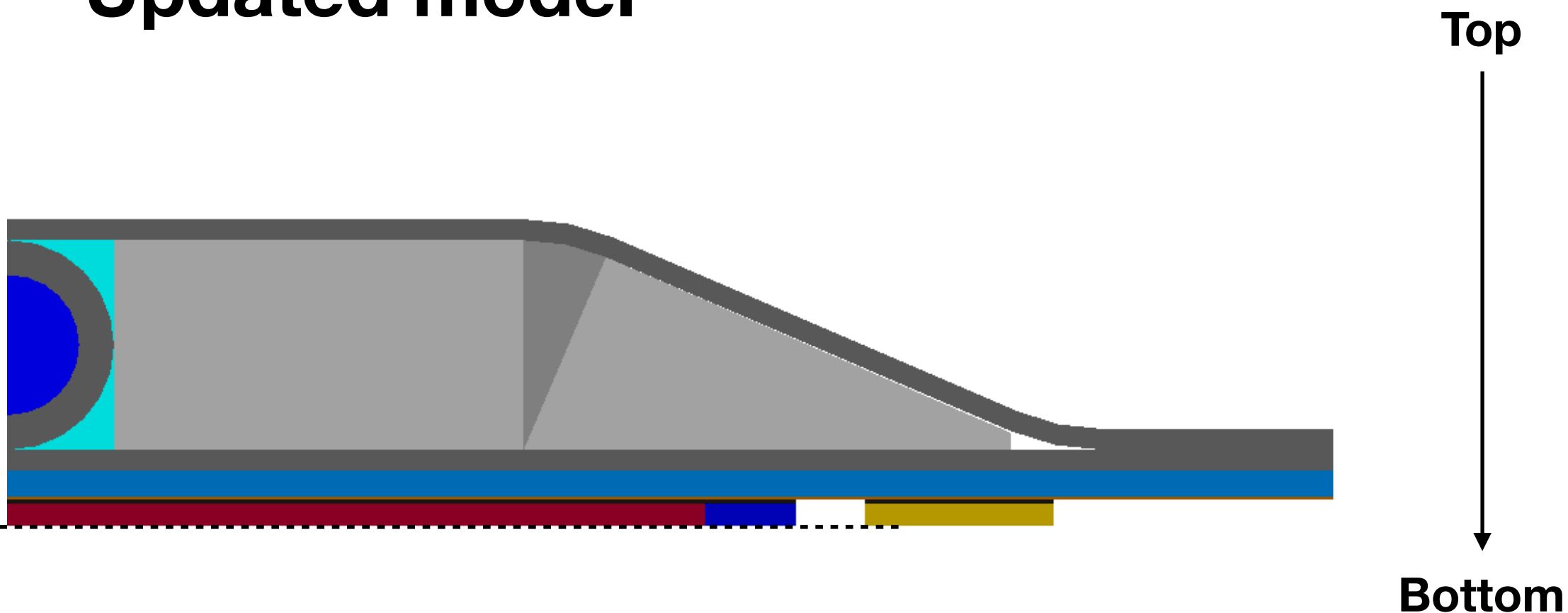
	Radiation Length (mm)	Fraction
CFC	194.0909	0.6
Epoxy	349.8941	0.4
Total	256.4122	
Water	360.8000	0.7
Glycol	349.2849	0.3
Total	356.7854	

Summary of Geometry of the ladder

Model in the current repository



Updated model



Top	Name	Materi	Thickne	X/X ₀
<div><div></div><div>Top</div><div>Bottom</div></div>	formed CFRP	CFRP	190.5	0.07%
	Rohacel, CFRP tube, water			0.13%
	PGS	CFRP	200	0.08%
	Kapton of HDI	Kapton	380	0.14%
	Copper of HDI	Copper	52	0.36%
	Sillicon/FPHX chips			0.30%
				1.08%
Botto m				

Top	Name	Materi	Thickne	X/X ₀	
<div><div></div><div>Top</div><div>Bottom</div></div>	formed CFRP	CFRP	300	0.12%	?
	Rohacel, CFRP tube, water			0.13%	
	flat CFRP	CFRP	300	0.12%	
	Kapton of HDI	Kapton	380	0.14%	
	Copper of HDI	Copper	37.6	0.26%	
	Silver epoxy glue	Ag, epoxy	50	0.26%	
				0.30%	
				1.32%	

Implementation

~Usability or Safety?~

There are 2 choices to change the geometry:

- Changing parameters at **source level**
Only experts touch
- Changing parameters at **macro level**
Any end-users can touch

Implementation

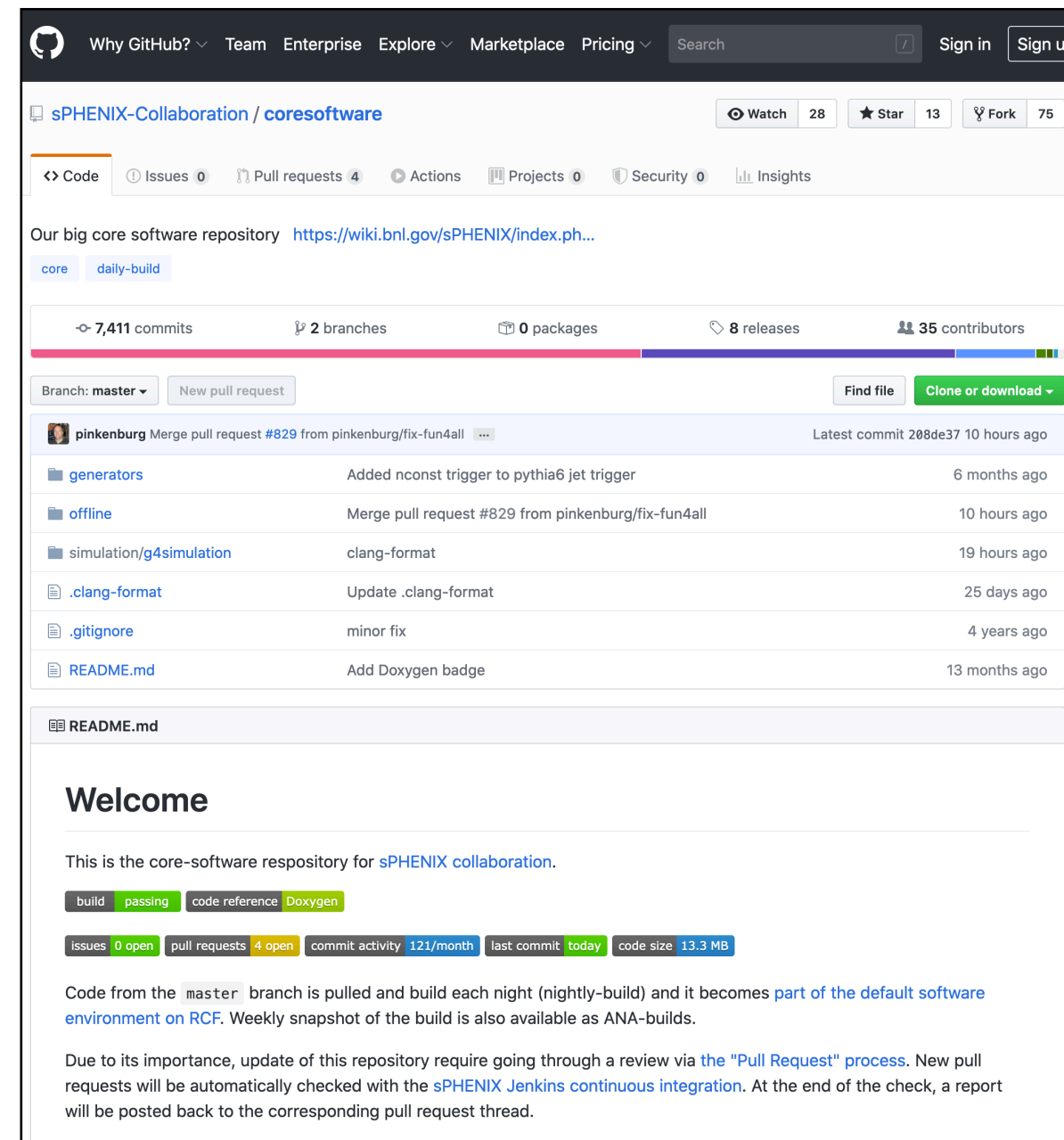
~Usability or Safety?~

There are 2 choices to change the geometry:

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Only experts touch
- Changing parameters at **macro level**
Any end-users can touch

Steps to run the simulation

1. in coresoftware repository,
making a shared library (libg4intt.so) etc.



coresoftware repository

```
├── generators
├── offline
├── simulation
│   └── g4simulation
│       ├── g4detectors
│       ├── g4dst
│       ├── g4eval
│       ├── g4gdml
│       ├── g4histos
│       ├── g4intt
│       ├── g4jets
│       ├── g4main
│       └── . . .
```

building shared lib. etc.

libg4intt.so etc.

Implementation

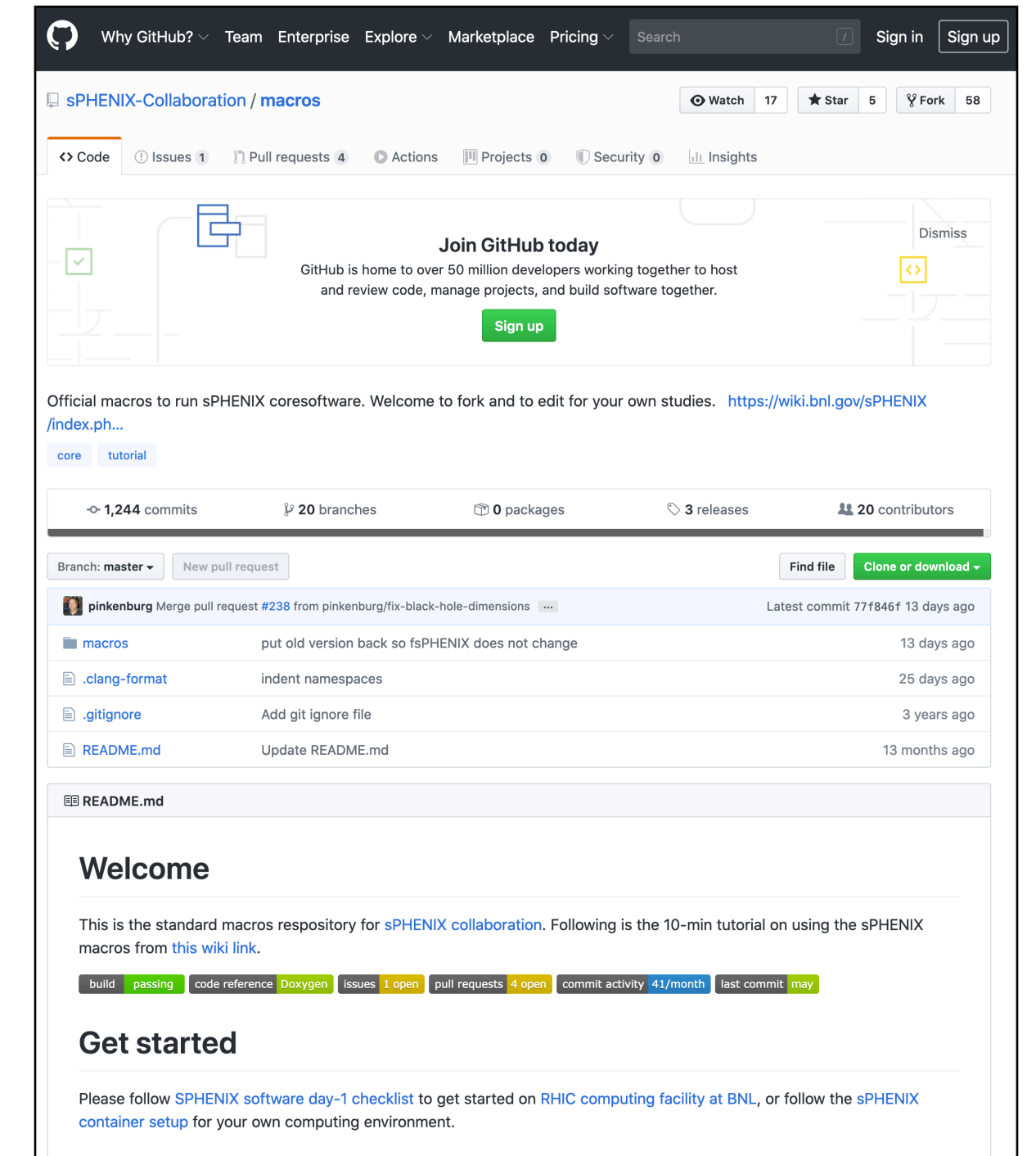
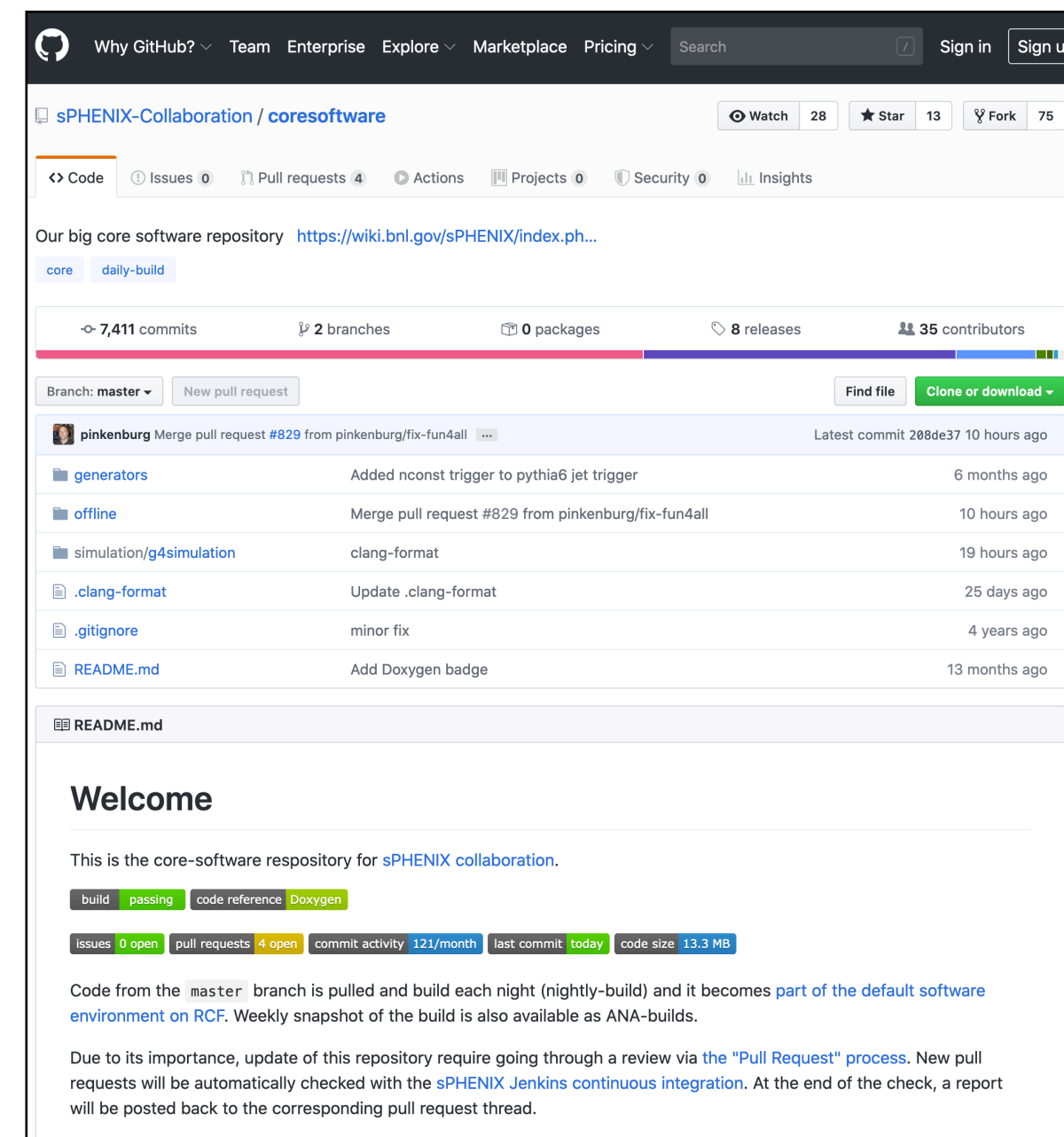
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Steps to run the simulation

1. in coressoftware repository,
making a shared library (libg4intt.so) etc.
2. in macro repository,
running Fun4All_sPHENIX.C
 - Fun4All_sPHENIX.C uses G4_Tracking.C to construct INTT.
 - Parameters can be changed in G4_Tracking.C.



coressoftware repository

```
├── generators
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│   └── g4simulation
│       ├── g4detectors
│       ├── g4dst
│       ├── g4eval
│       ├── g4gdm1
│       ├── g4histos
│       ├── g4intt
│       ├── g4jets
│       └── g4main
│       . . .
```

building shared lib. etc.

libg4intt.so etc.

macros repository

```
├── README.md
├── macros
│   ├── QA
│   ├── g4simulations
│   │   ├── Fun4All_G4_sPHENIX.C
│   │   ├── G4_Tracking.C
│   │   . . .
│   └── sPHENIXStyle
```

feeding shared lib. etc.

Implementation

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Only experts touch
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Any end-users can touch

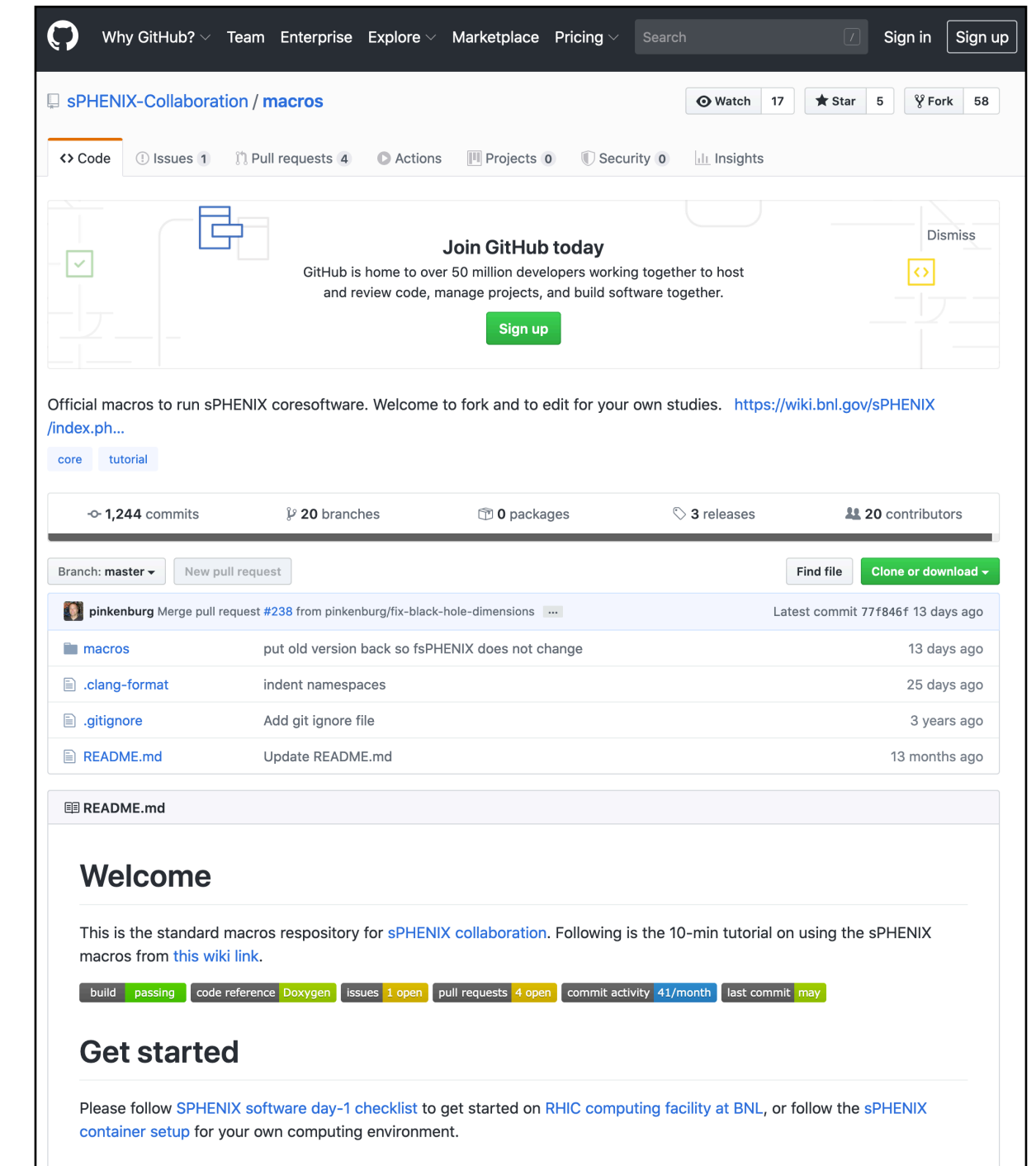
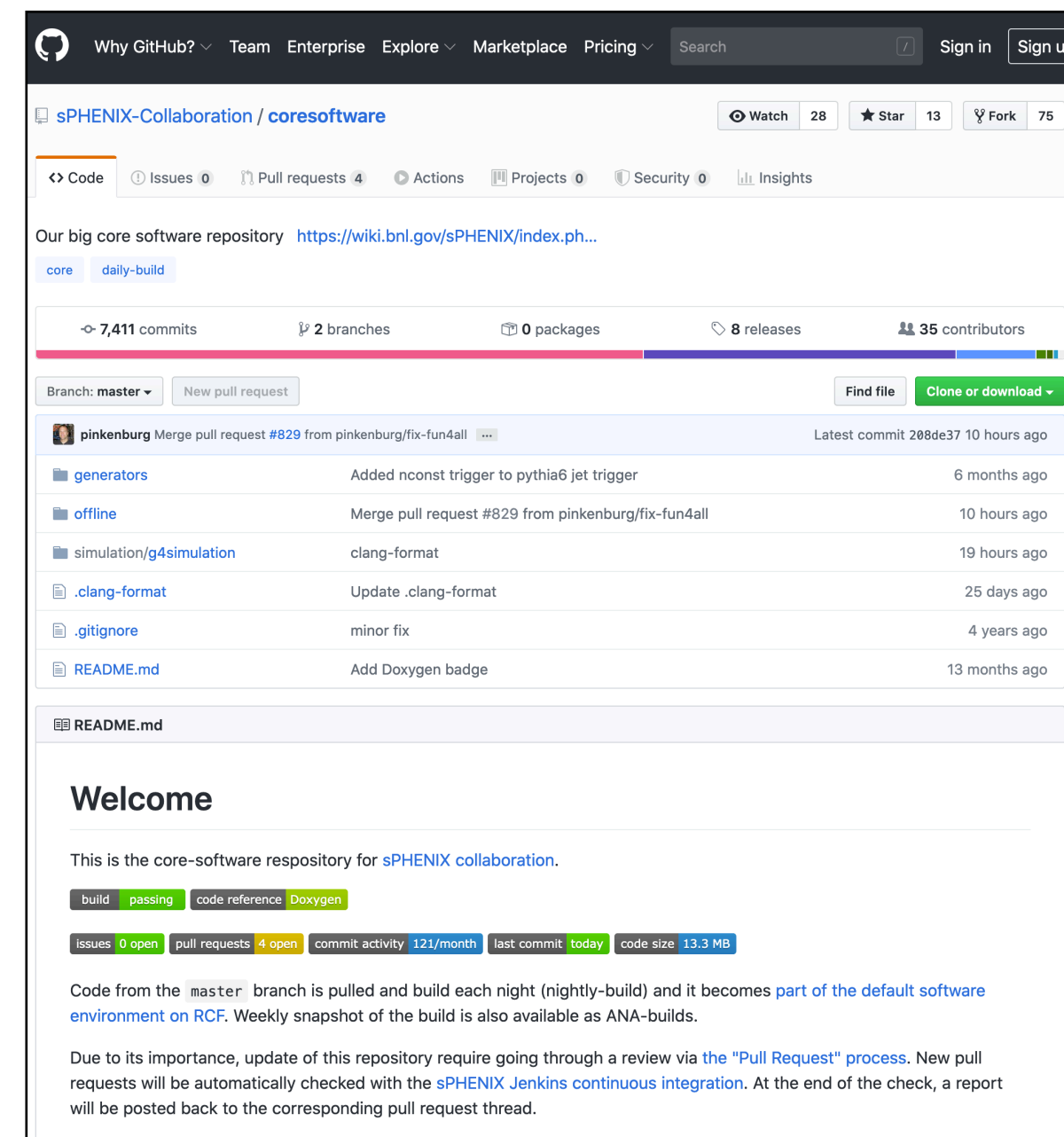
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running Fun4All_sPHENIX.C
 - Fun4All_sPHENIX.C uses G4_Tracking.C to construct INTT.
 - Parameters can be changed in G4_Tracking.C.

Parameters in the source are hard corded.

Users can change parameters in the macro,
so it's useful but danger.

When parameters can be fixed, it may be good to
disable to change them at the macro level.



coressoftware repository

```
├── generators
├── offline
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└── sPHENIXStyle
```

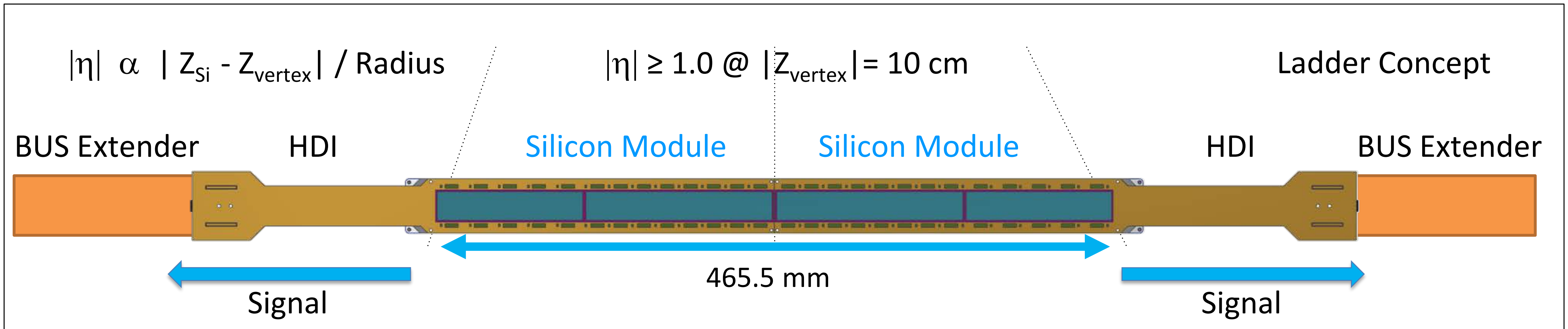
building shared lib. etc.

libg4intt.so etc.

feeding shared lib. etc.

backup

Two Barrel Configuration



Barrel	Center of Sensor Tangent Radius (mm)	Pseudo rapidity	QTY of Ladders	Angle (deg)	Coverage (PHI) (%)	Overlap (%)	Clearance (mm)	Chip Power Dissipation (W)	Stave Rad Length (%)	Barrel Rad Length (%)
1	-	-	24	-	100	1.8	2.0	62.30	0.80	2.20
1a (Inner)	71.88	1.37	12	0	52.7	0	0.6	31.15	0.40	1.10
1b (Outer)	77.32	1.31	12	0	49.4	0	3.6	31.15	0.40	1.10
2	-	-	32	-	100	1.8	2.0	83.07	0.80	2.20
2a (Inner)	96.80	1.12	16	0	52.4	0	0.6	41.53	0.40	1.10
2b (Outer)	102.62	1.07	16	0	49.4	0	3.0	41.53	0.40	1.10
Total	-	-	56	-	-	100	11.22	145.37	1.60	4.40

Layer Structure of HDI



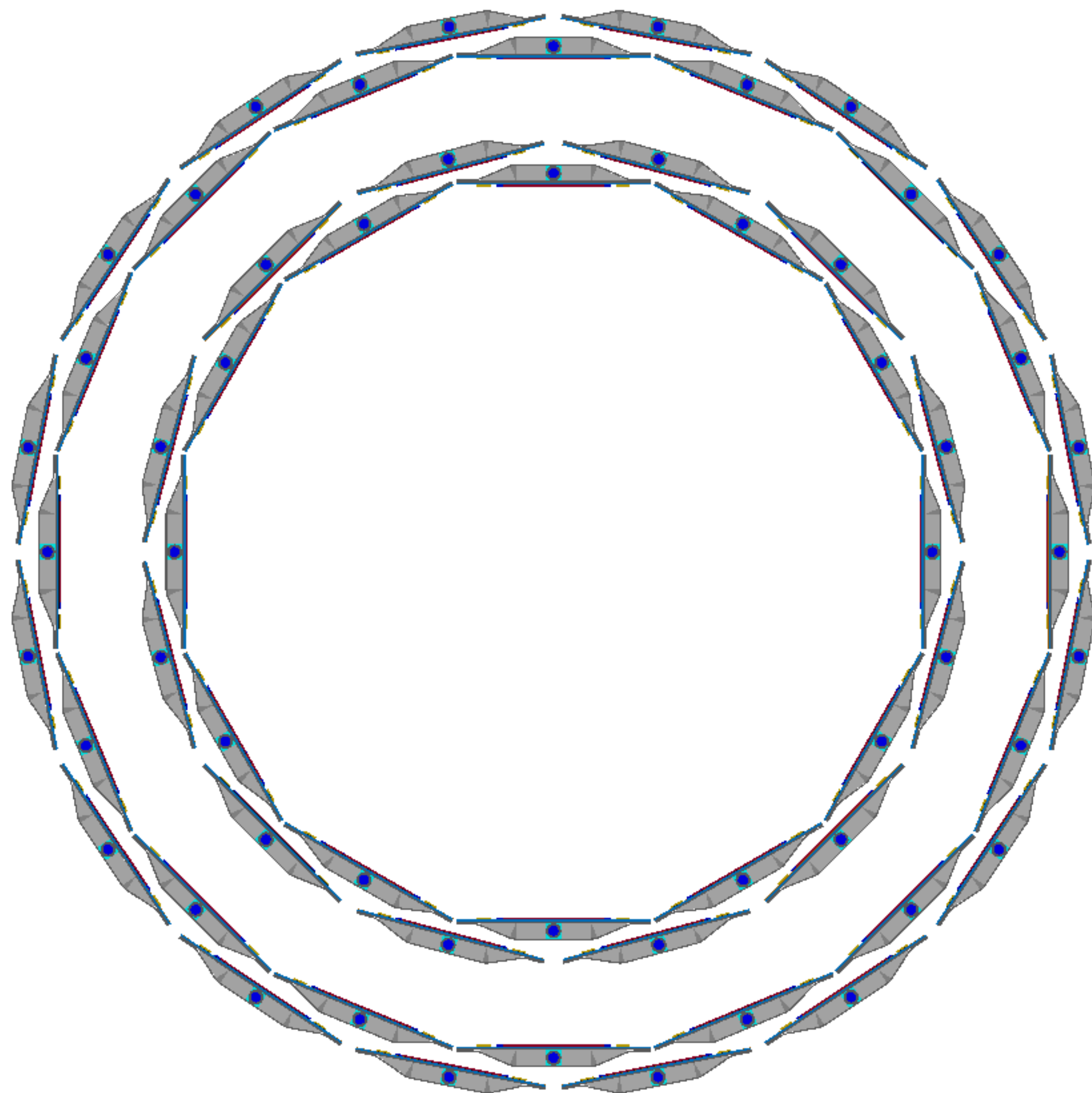
Regist	20 μ m	
Copper plated	15 μ m	
L1 Electrolytic copper foil	9 μ m	HVLINE+AGND
Base Polyimide	50 μ m	
L2 Electrolytic copper foil	9 μ m	A GND
Glue	25 μ m	
Base Polyimide	12.5 μ m	
Glue	15 μ m	
L3 Electrolytic copper foil	9 μ m	RF LINE
Base Polyimide	50 μ m	
L4 Electrolytic copper foil	9 μ m	PWR
Glue	25 μ m	
Base Polyimide	12.5 μ m	
Glue	15 μ m	
L5 Electrolytic copper foil	9 μ m	SIG
Base Polyimide	50 μ m	
L6 Electrolytic copper foil	9 μ m	D GND
Glue	25 μ m	
Base Polyimide	25 μ m	
L7 Electrolytic copper foil	9 μ m	
Copper plated	15 μ m	
Regist	20 μ m	
	μ m	
	438 μ m	
TOTAL厚	438 μ m	

Coverlay Polyide	12.5 μ m
Coverlay Glue	25 μ m
Copper plated	15 μ m
L1 Electrolytic copper fo	9 μ m
Base Polyimide	50 μ m
L2 Electrolytic copper fo	9 μ m
Glue	25 μ m
Base Polyimide	12.5 μ m
Glue	15 μ m
L3 Electrolytic copper fo	9 μ m
Base Polyimide	50 μ m
L4 Electrolytic copper fo	9 μ m
Glue	25 μ m
Base Polyimide	12.5 μ m
Glue	15 μ m
L5 Electrolytic copper fo	9 μ m
Base Polyimide	50 μ m
L6 Electrolytic copper fo	9 μ m
Glue	25 μ m
Base Polyimide	25 μ m
L7 Electrolytic copper fo	9 μ m
Copper plated	15 μ m
Coverlay Glue	25 μ m
Coverlay Polyimide	12.5 μ m
Glue for support plate	40 μ m
Support Plate FR-4 1	1000 μ m

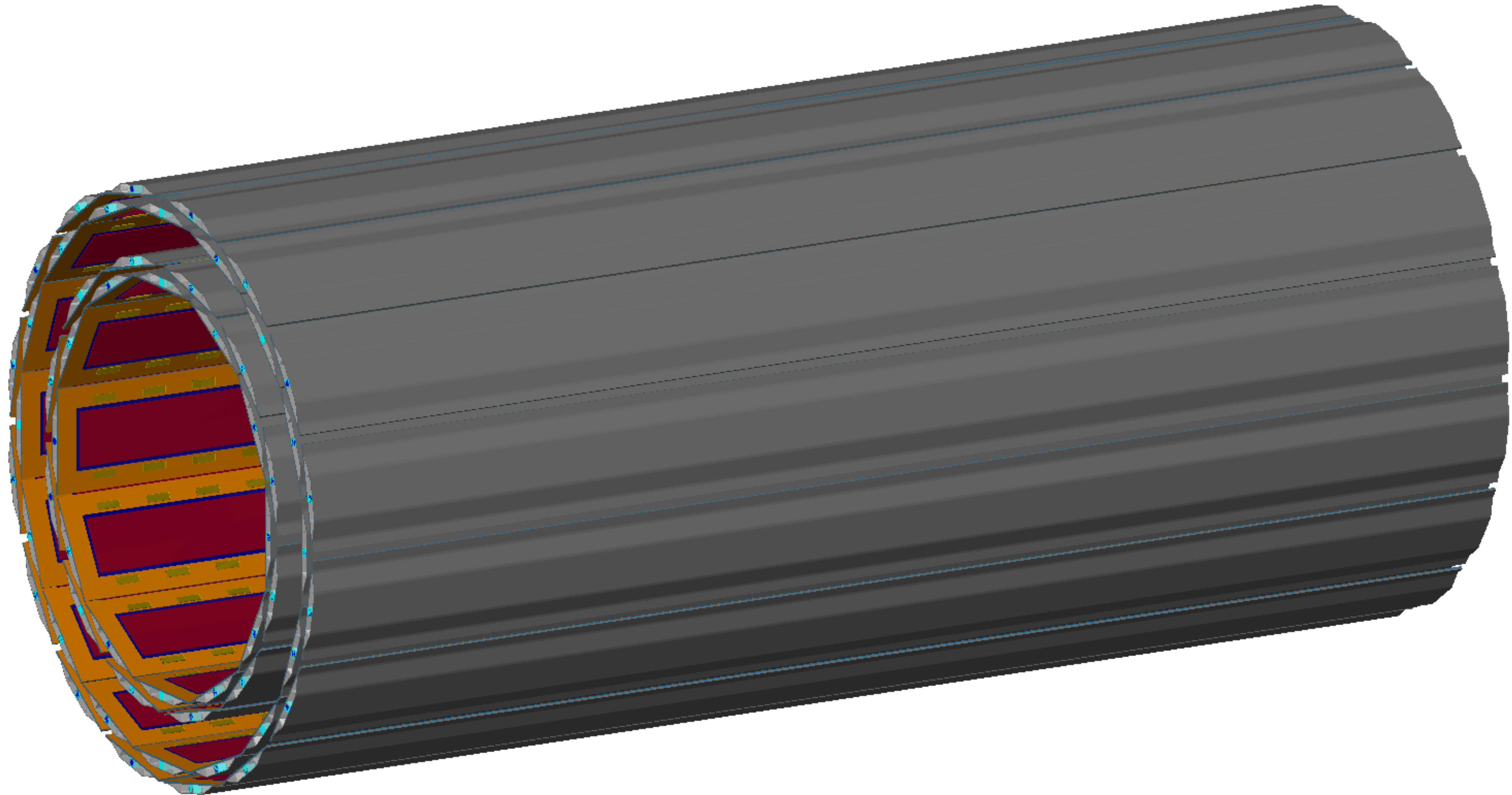
TOTAL厚 473 μ m

Sub Component Thickness					
Occupancy	Copper Layers		Else		
	Effecti	Real			
	ve[μ	[μ m]			
	m]				
				12.5	
				25	
	71.3%	10.69	15		
		0.00	9		
				50	
	93.5%	8.42	9		
				25	
				12.5	
				15	
	6.50%	0.59	9		
				50	
	94.0%	8.46	9		
				25	
				12.5	
				15	
	7.20%	0.65	9		
				50	
	93.2%	8.38	9		
				25	
				25	
	4.68%	0.42	9		
		0.00	15		
				25	
				12.5	
Total	37.605	93	380		
Radiation Length [1.435		28.6	Total	
X/Xrad [%]	0.262		0.1329	0.3949	

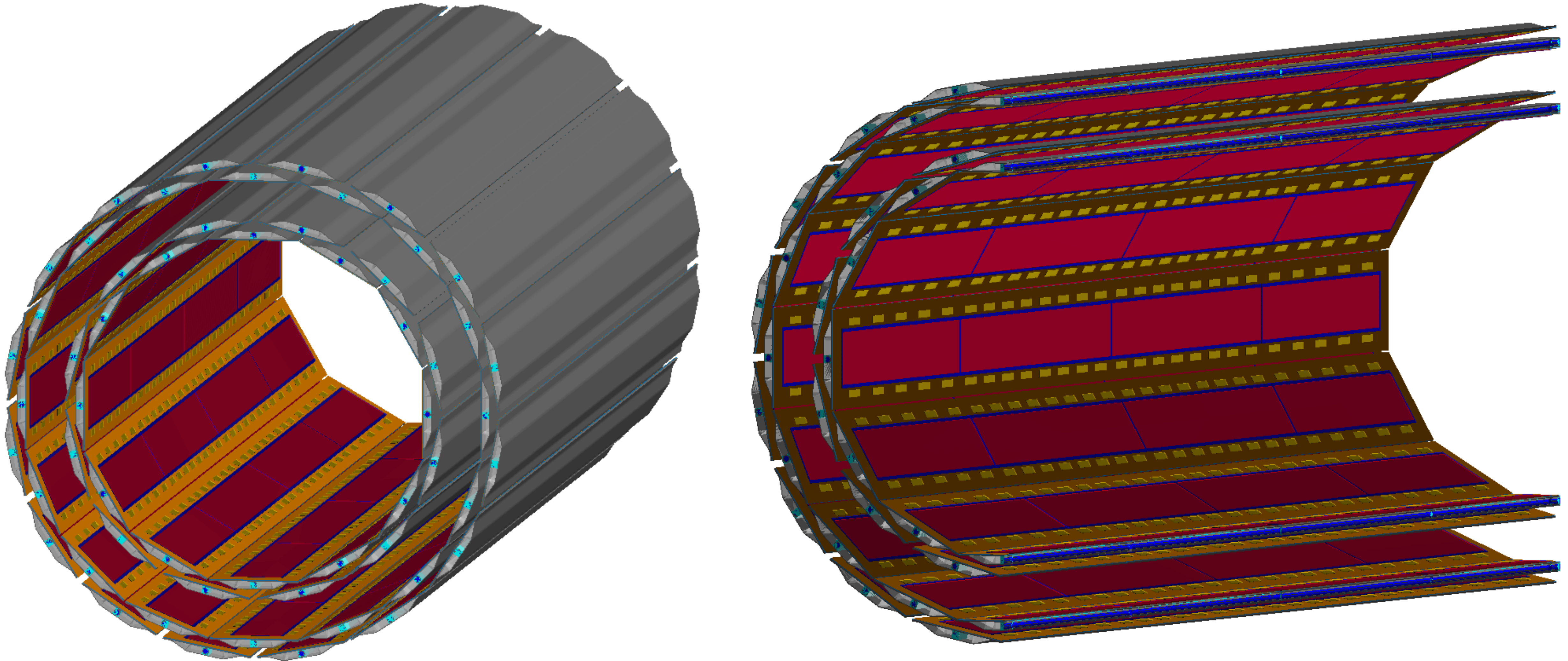
Gallery of the updated model



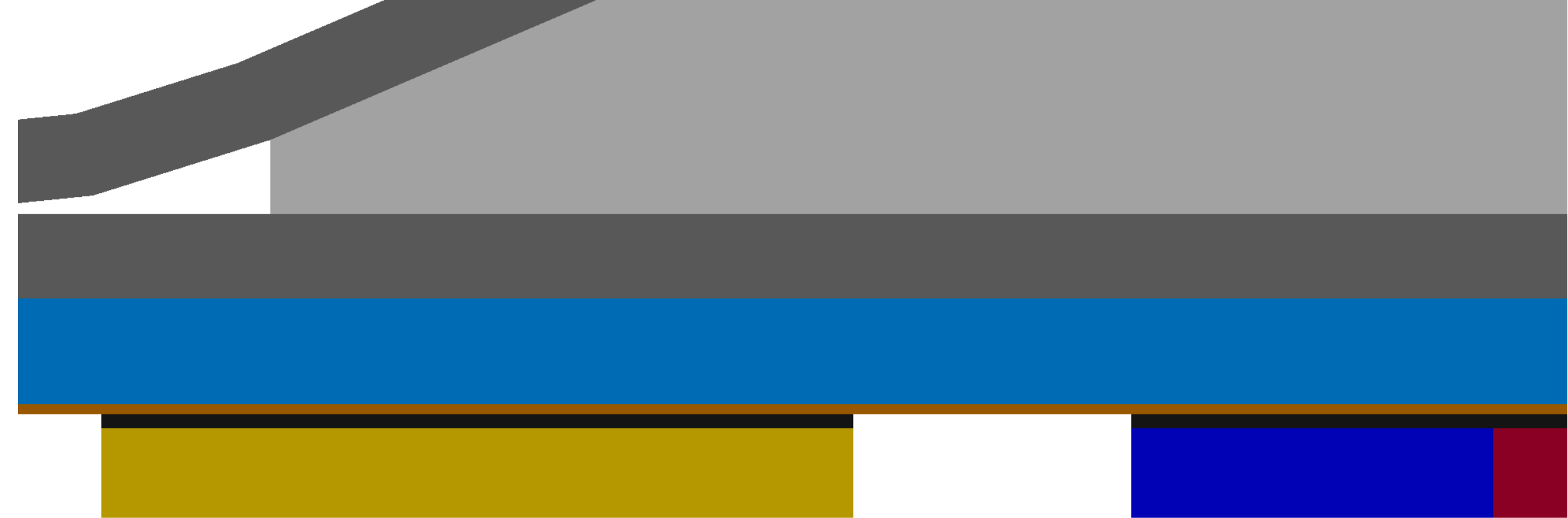
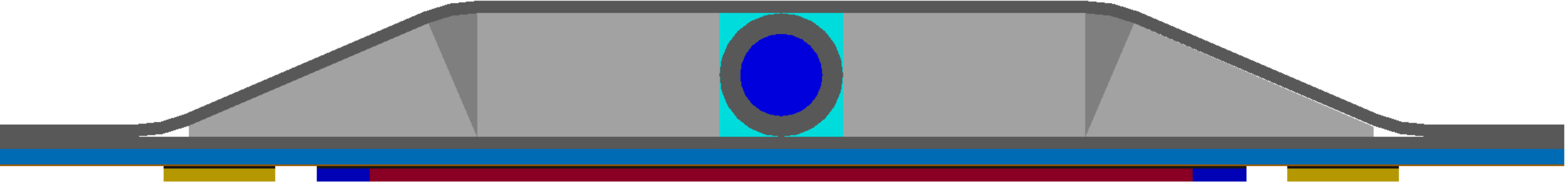
Gallery of the updated model



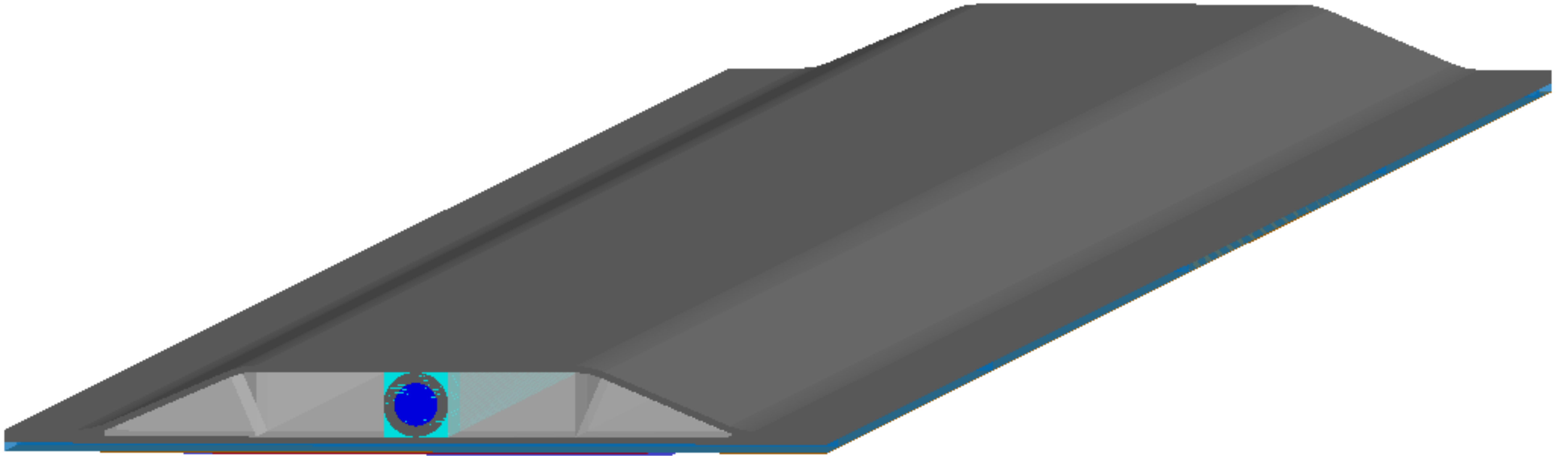
Gallery of the updated model



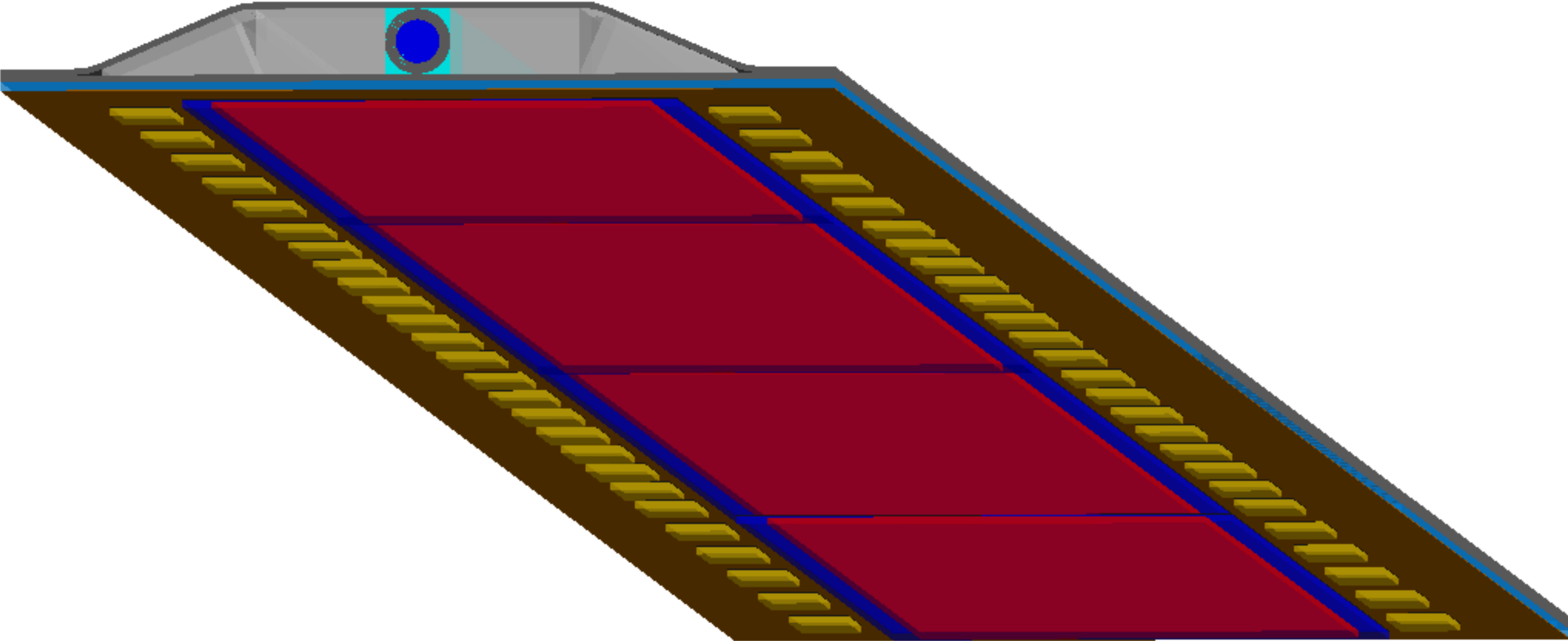
Gallery of the updated model



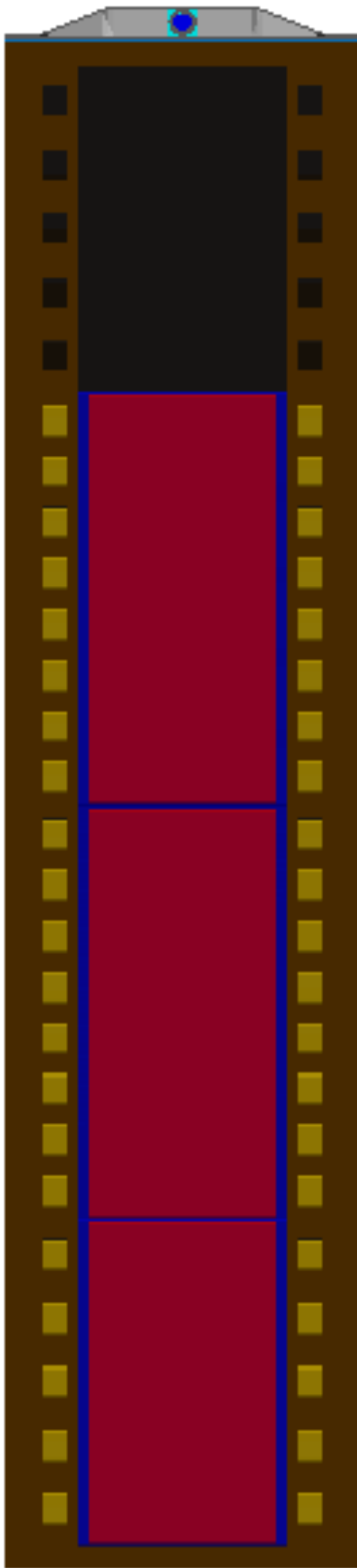
Gallery of the updated model



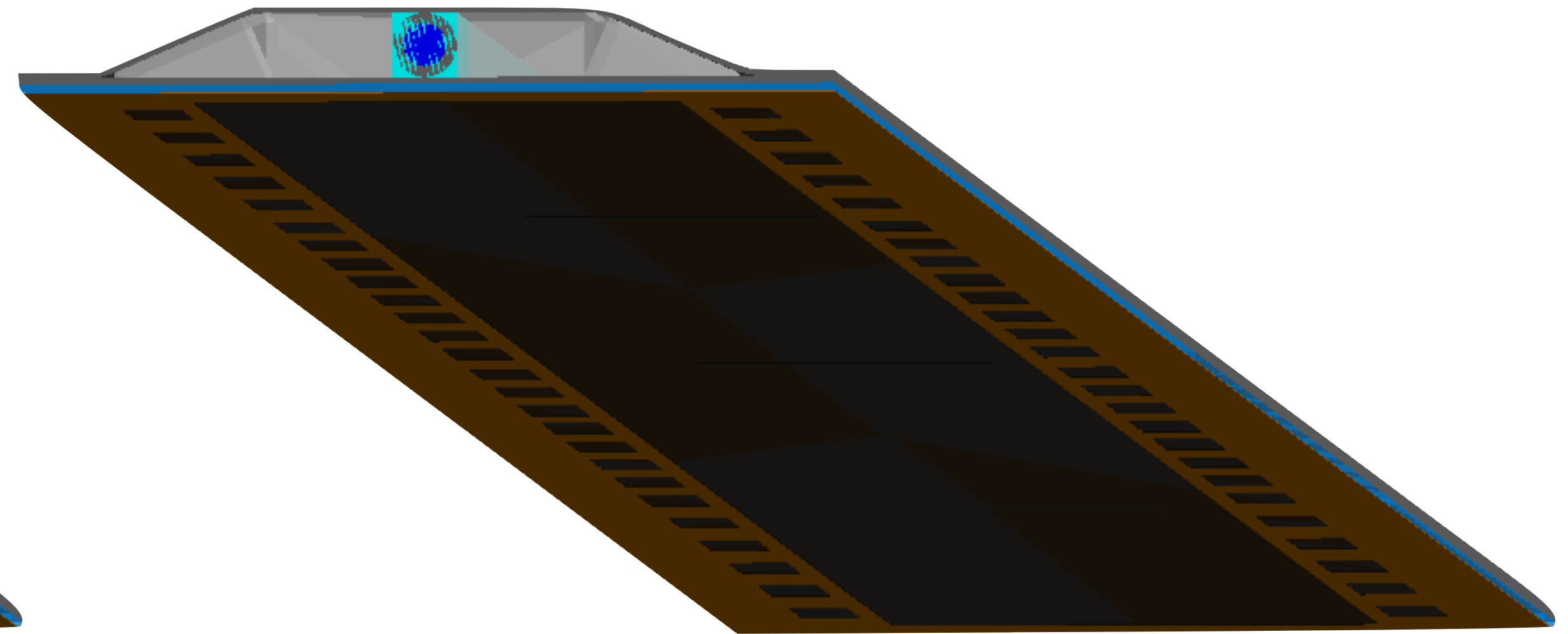
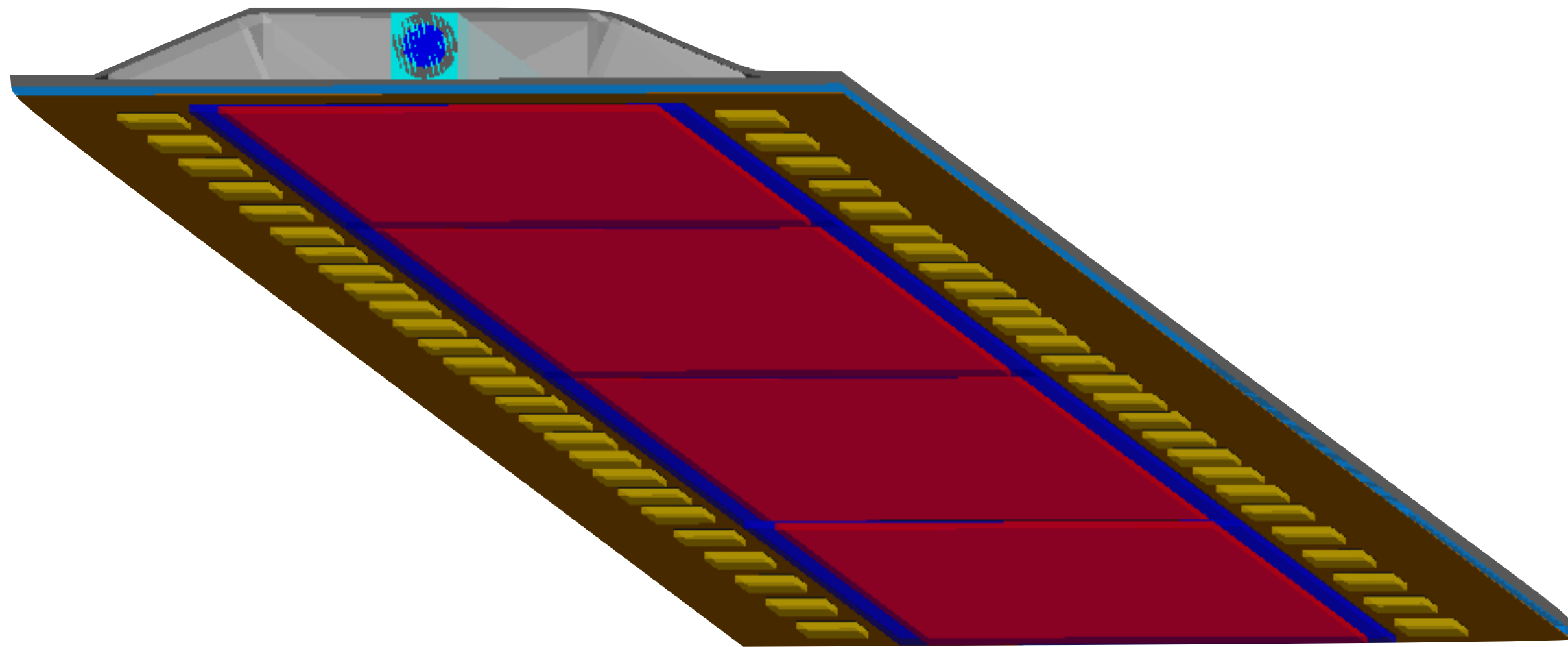
Gallery of the updated model



Gallery of the updated model

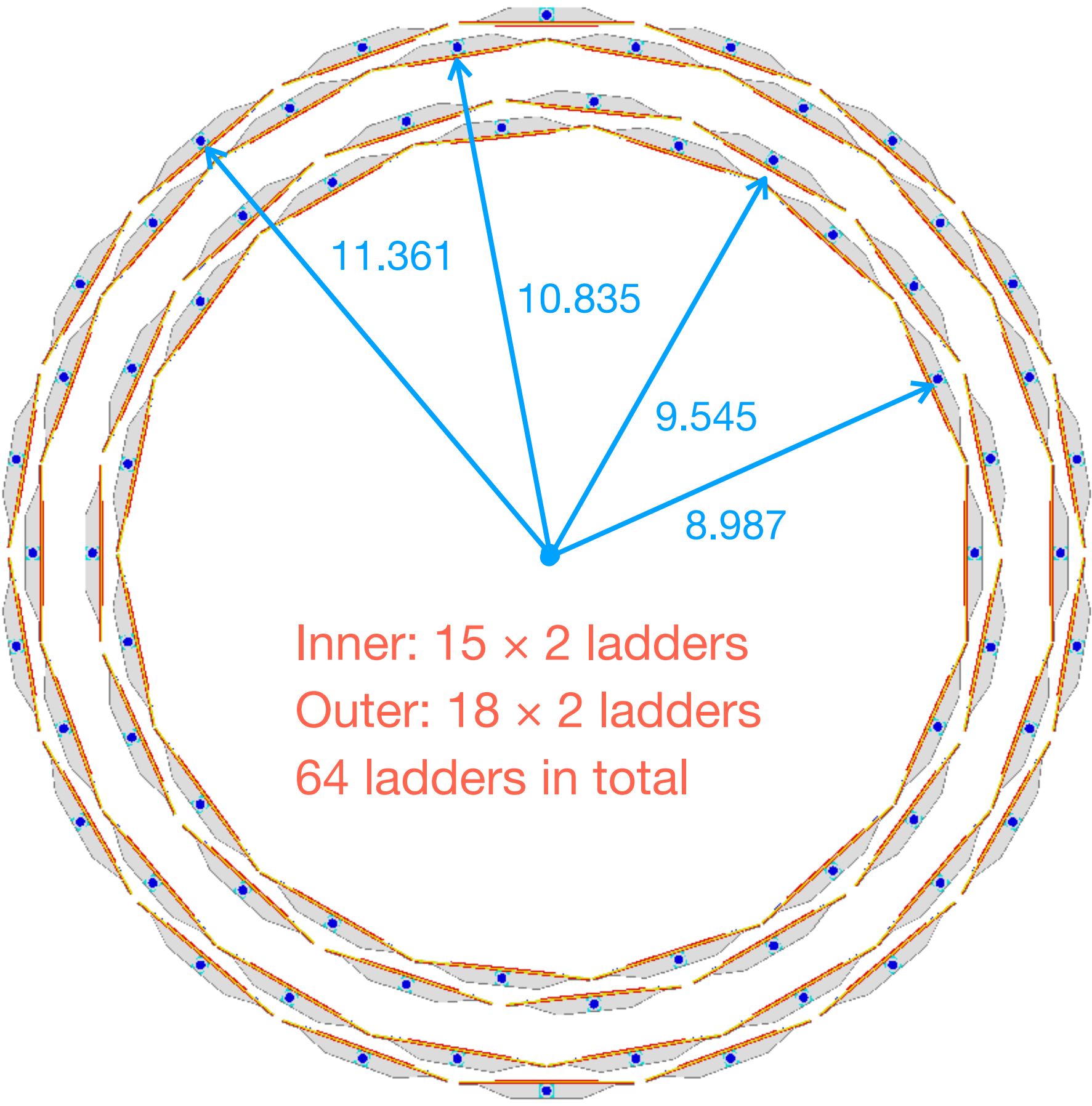
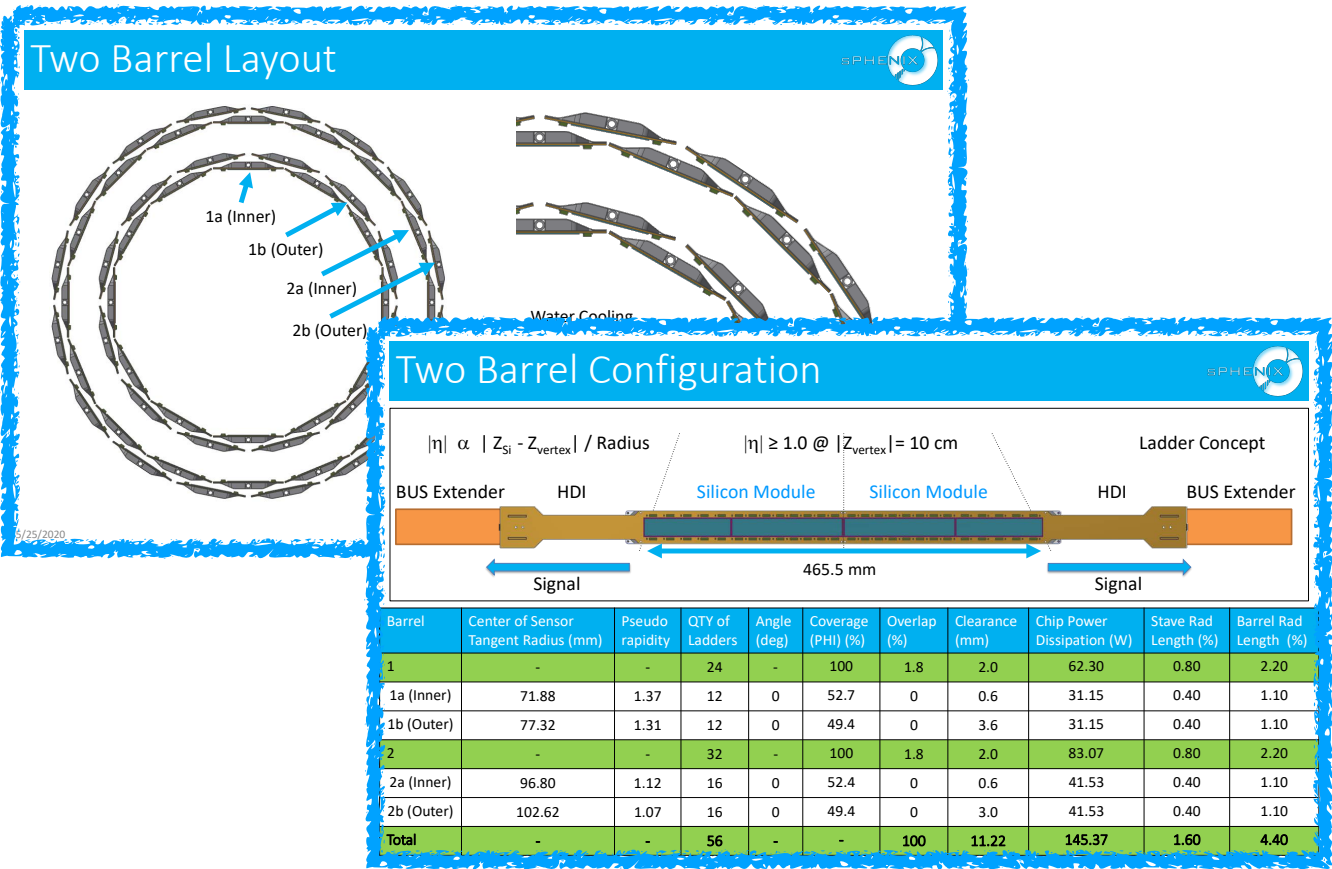


Gallery of the updated model

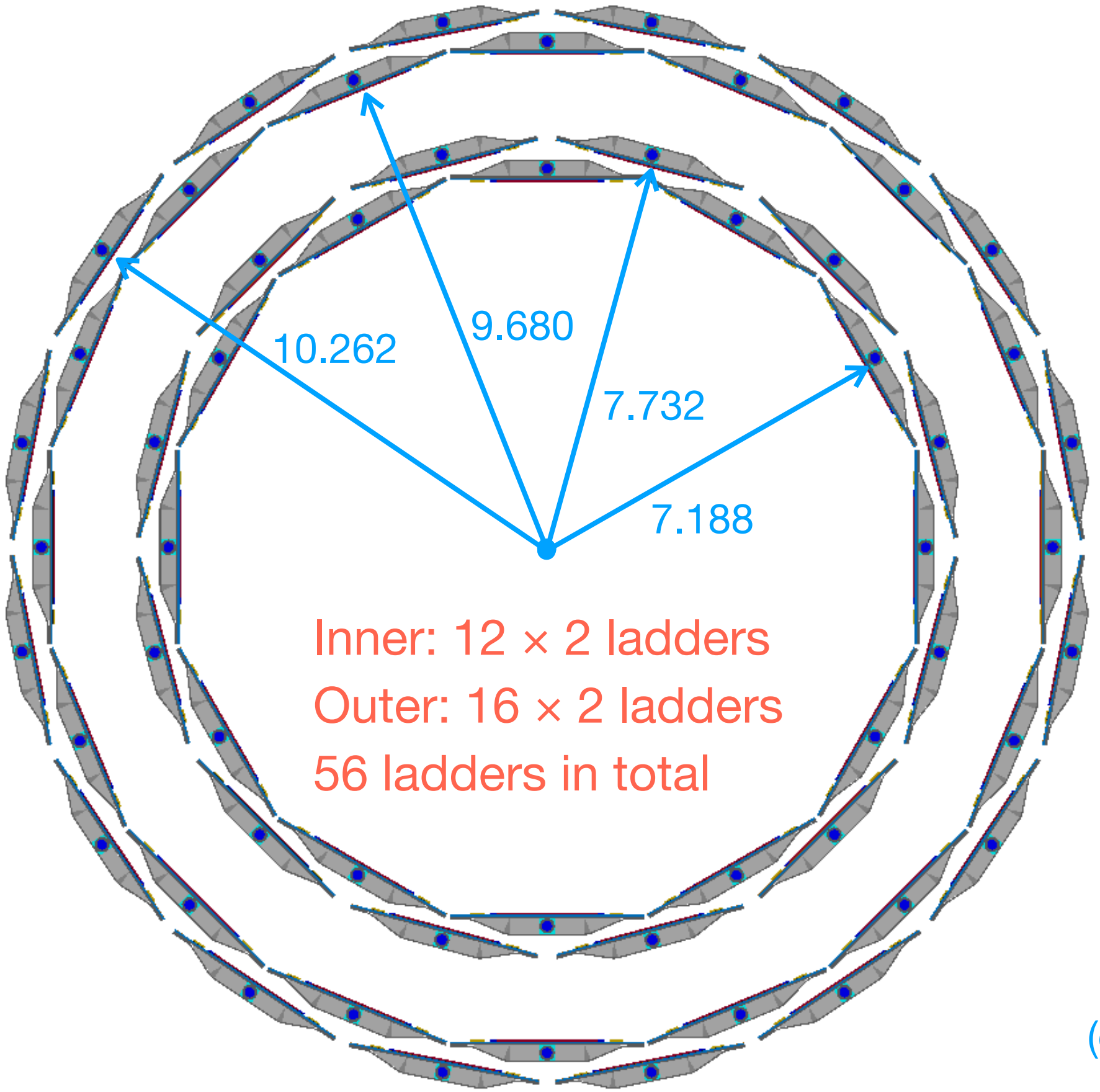
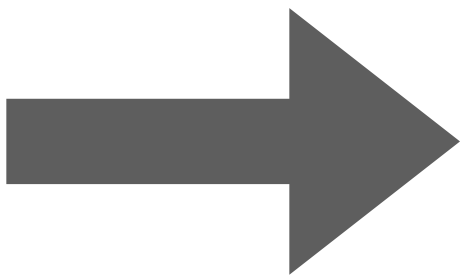


Layout updated

Dan provided the information! →

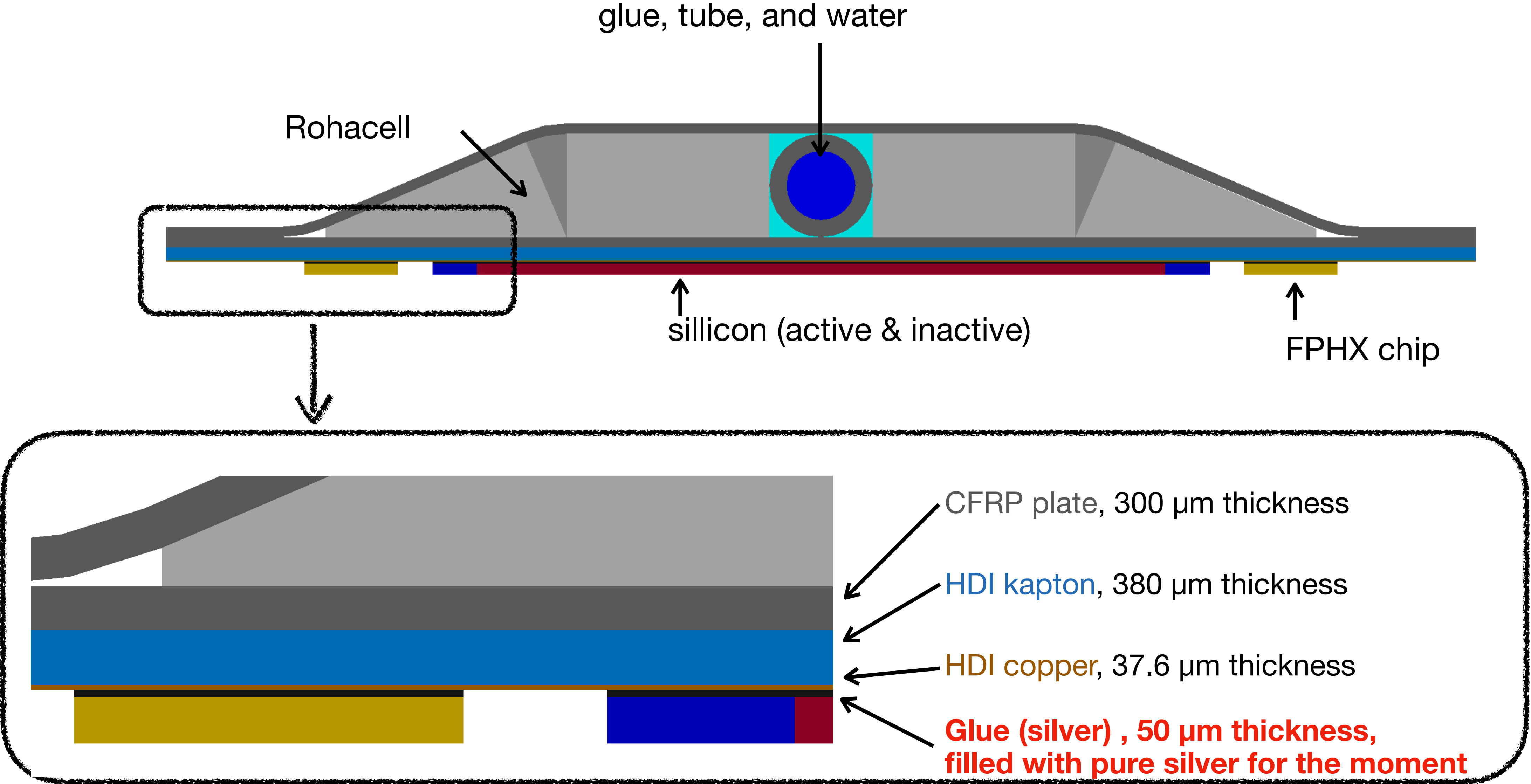


Model in the current repository

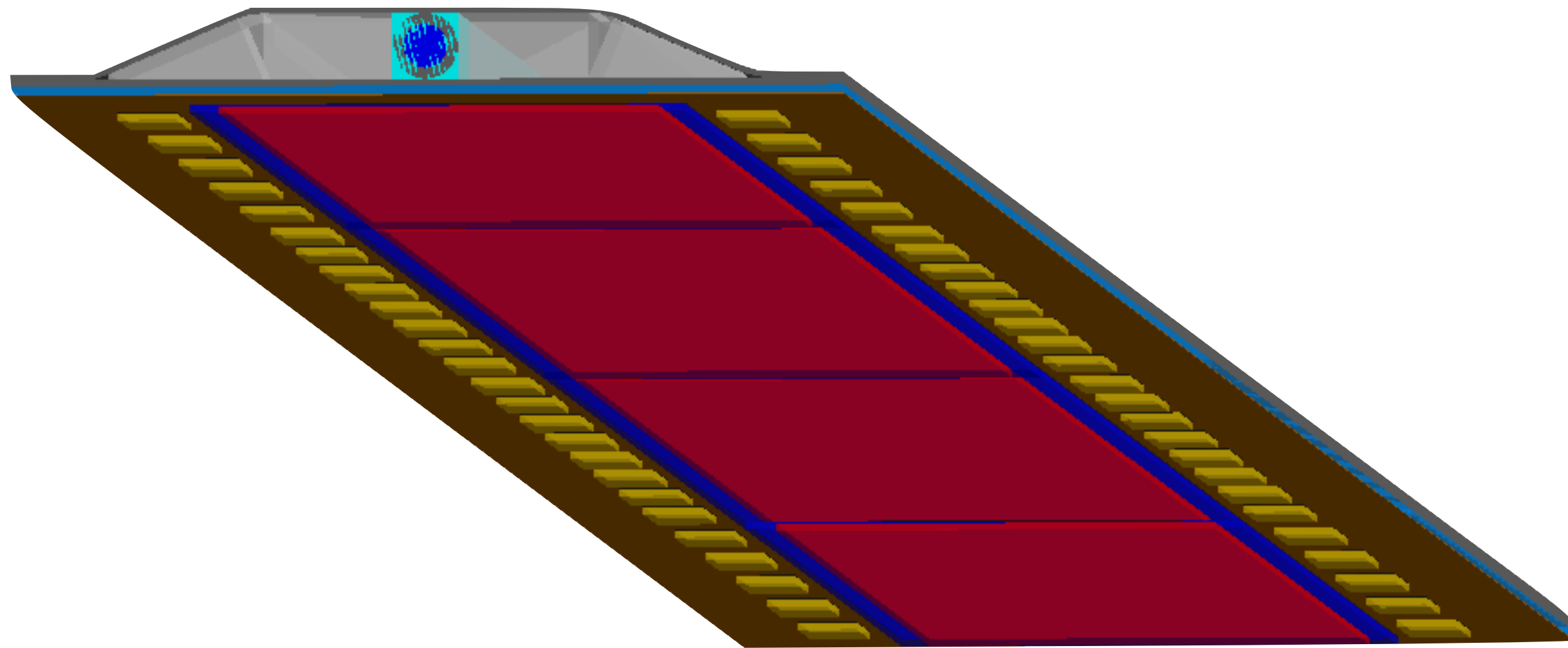


Updated model

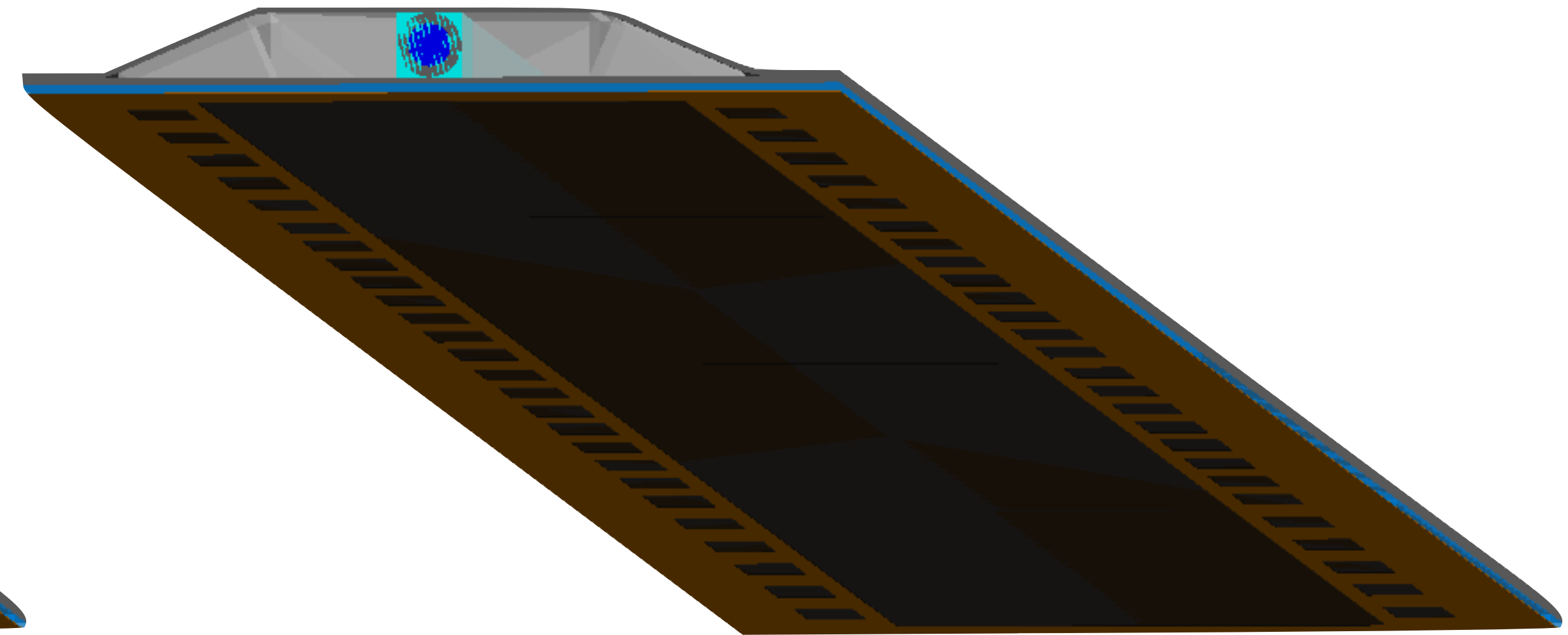
Geometry of a ladder



Geometry of a ladder



View from bottom

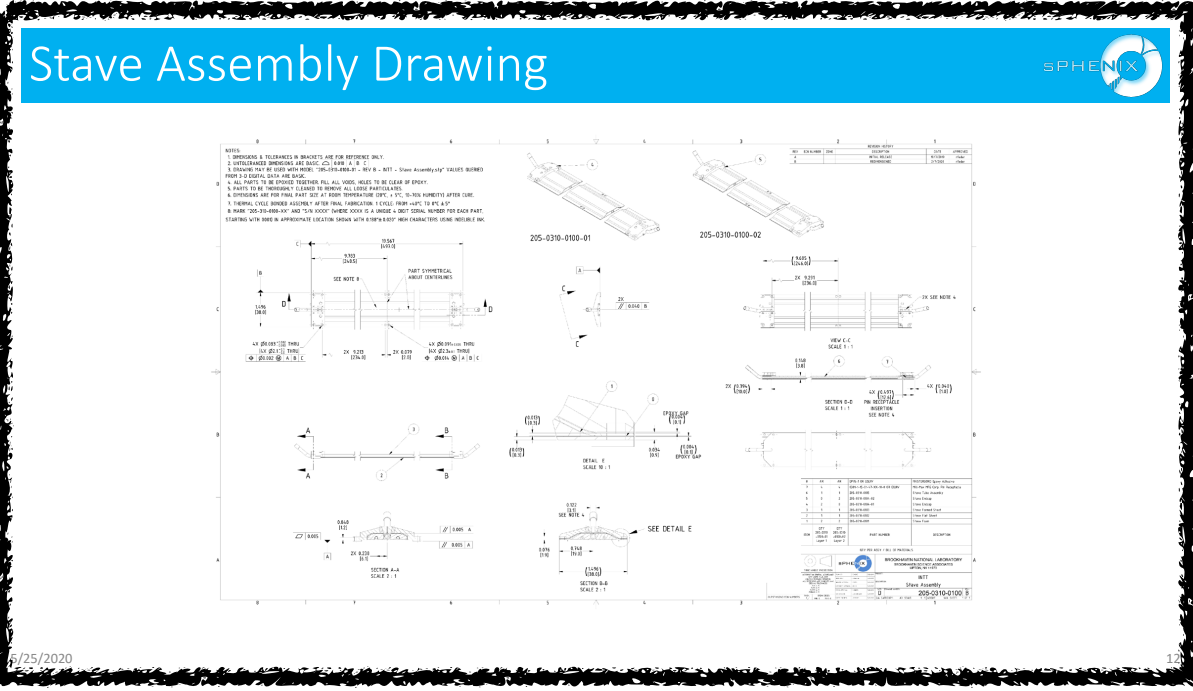
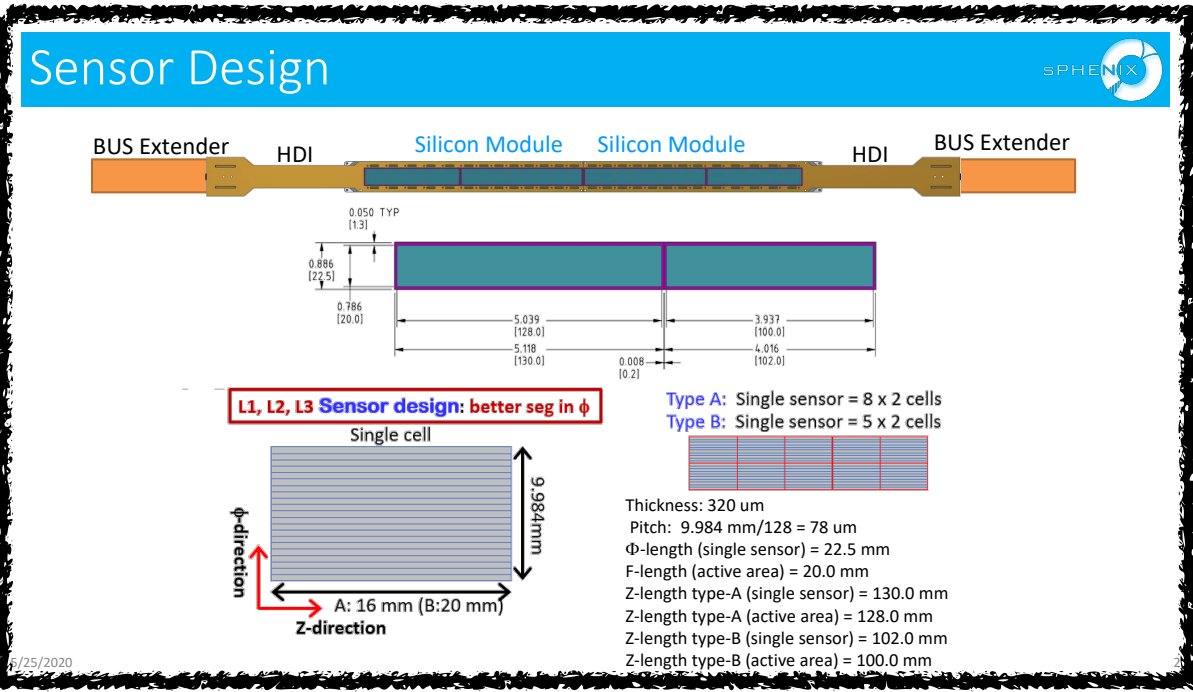


Silicon sensors and
FPHX chips removed

Size of glue is exactly the same as silicon's and chips'.

Geometry of a ladder, dimension

No major discrepancy was found in the Geant4 codes for the moment although I need to take more time to understand Dan’s drawing.

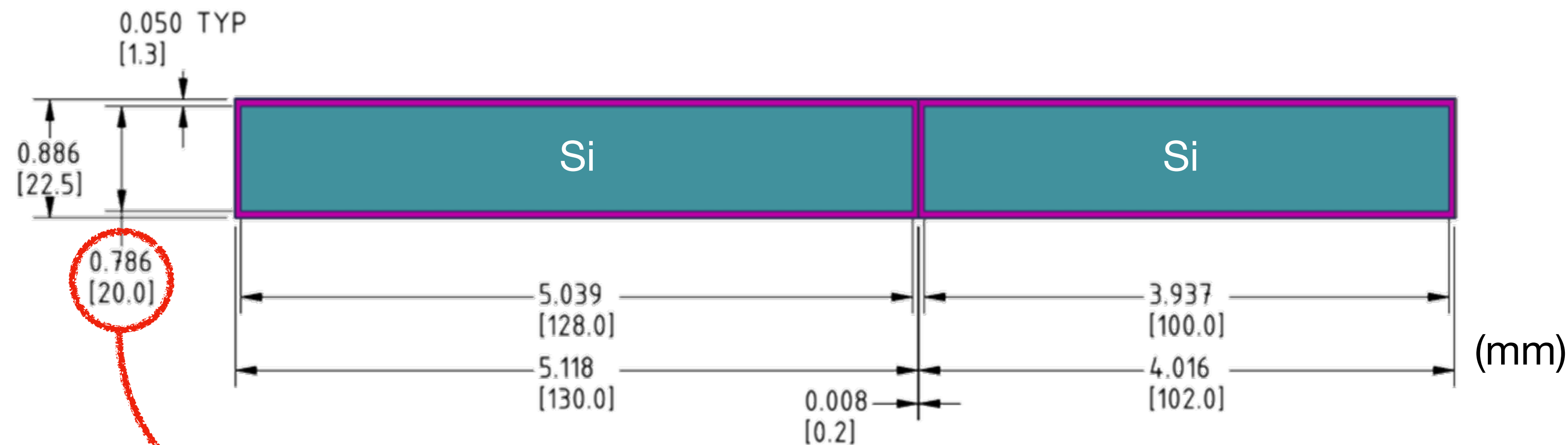


Dan provided the information!

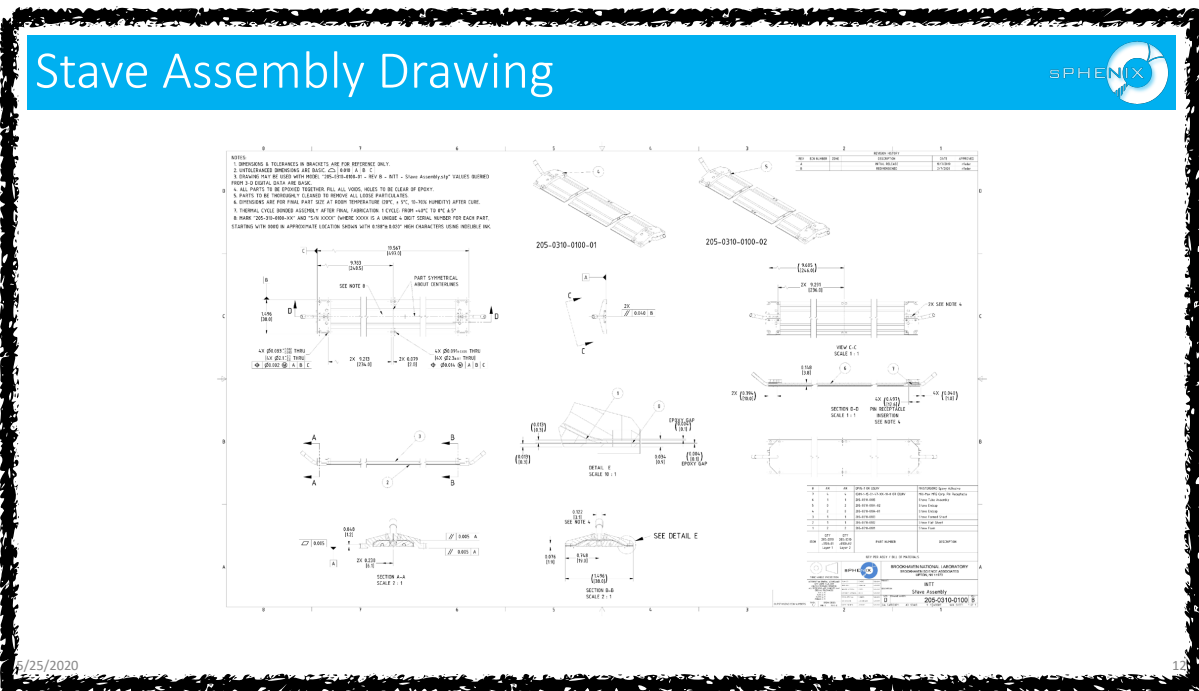
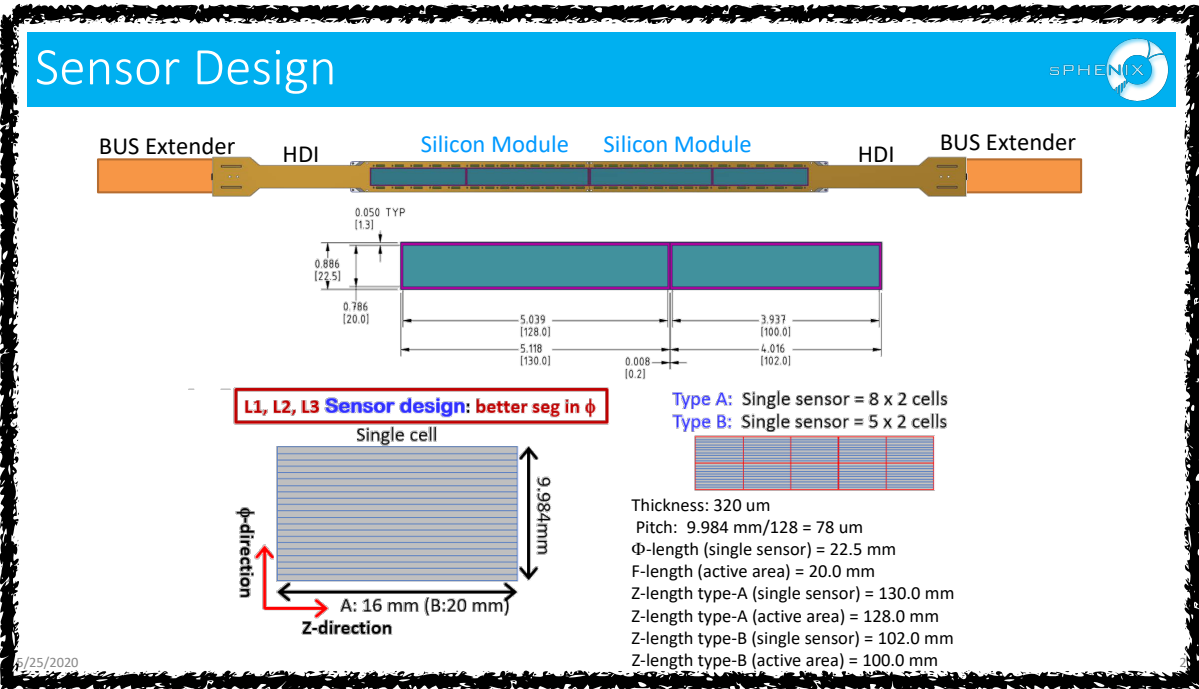
Geometry of a ladder, dimension

No major discrepancy was found in the Geant4 codes for the moment although I need to take more time to understand Dan’s drawing.

Minor difference I found:



Width of the silicone sensor in Geant: 0.0078 x 256 = 1.9968 cm

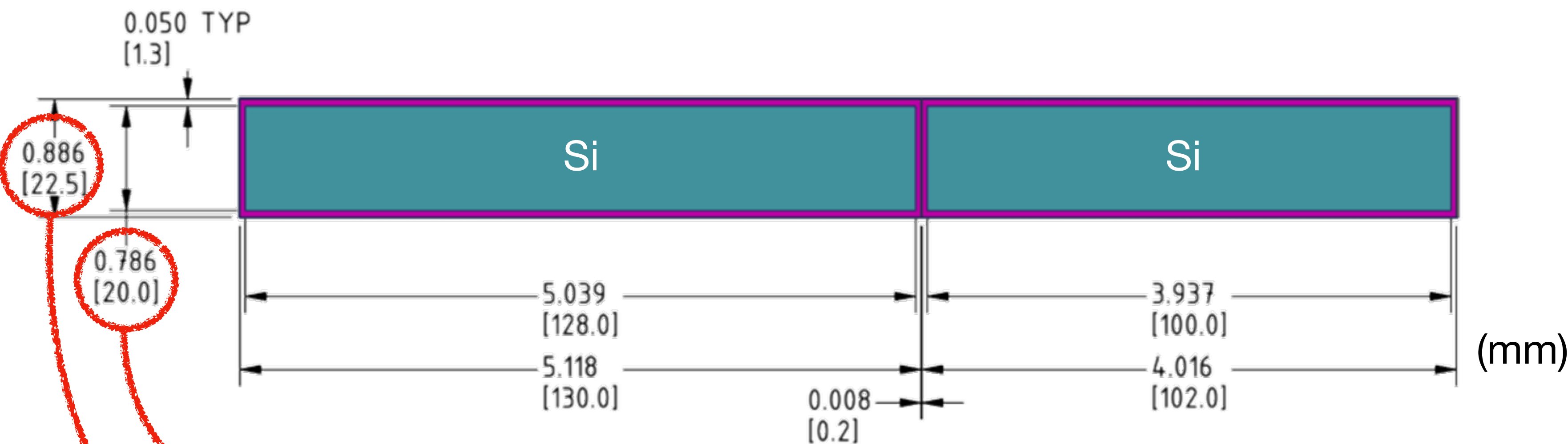


Dan provided the information!

Geometry of a ladder, dimension

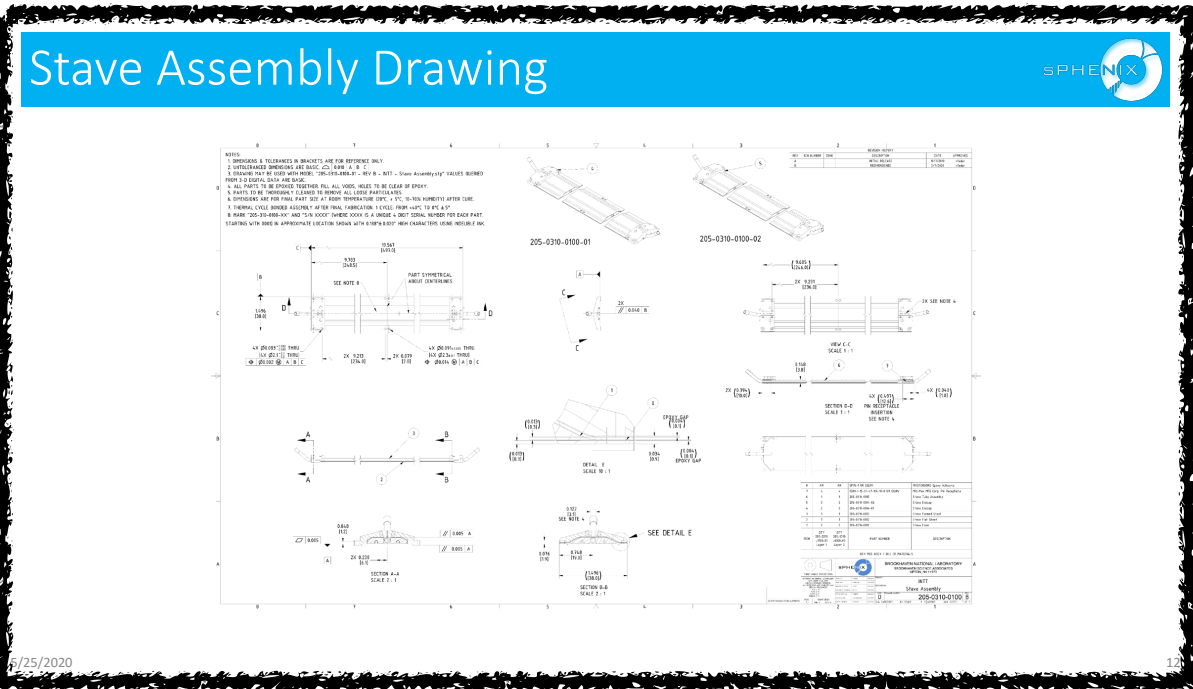
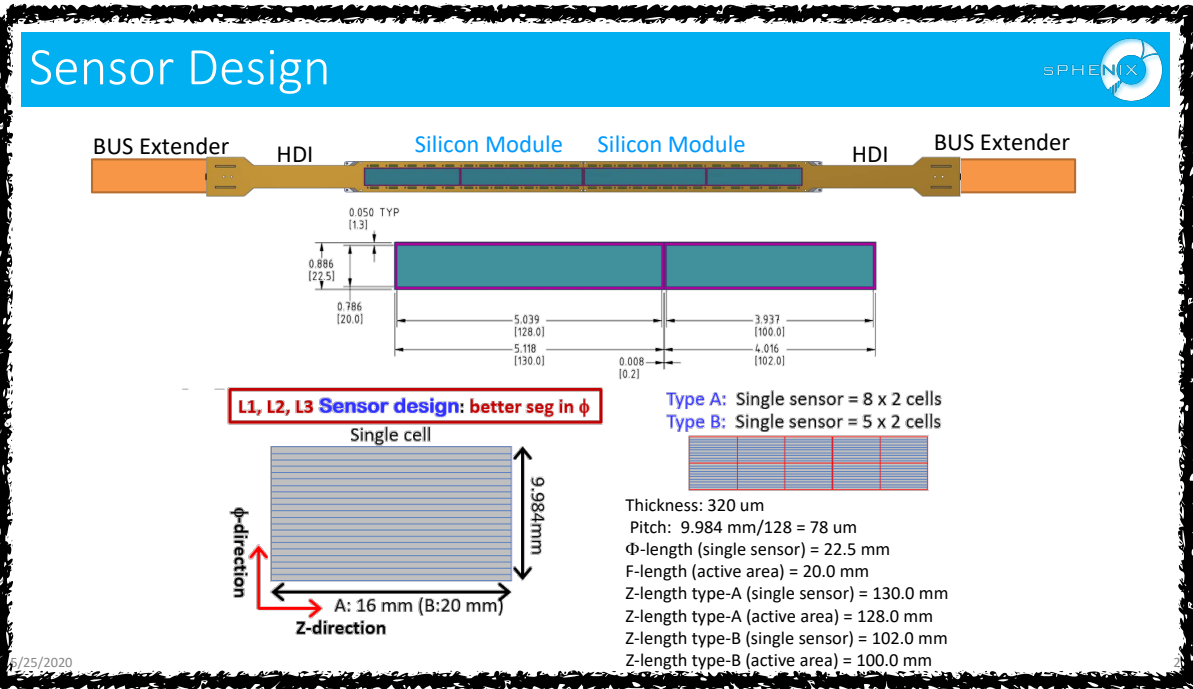
No major discrepancy was found in the Geant4 codes for the moment although I need to take more time to understand Dan's drawing.

Minor difference I found:



Width of the silicone sensor in Geant: $0.0078 \times 256 = 1.9968$ cm

Width of the silicone in Geant: $1.9968 + 2 \times 0.13 = 2.2568$ cm



Dan provided the information!

Ag, $X_0 = 8.543 \text{ mm}$, $10.5 \text{ } \mu\text{m}$, $X/X_0 = 0.123\%$

Epoxy, $X_0 = 299 \text{ mm}$, $39.5 \text{ } \mu\text{m}$, $X/X_0 = 0.013\%$

Radiation length in a composite material : $\frac{W}{X_0} = \sum \frac{W_i}{X_{0,i}}$ where $w_{(i)}$ is the total mass of the sample in g and $X_{0(i)}$ is radiation length in g/cm^2

$$\frac{W_{Ag}}{X_{0,Ag}} = \frac{10.5(\text{g/cc}) \times 10.5(\mu\text{m})}{8.97(\text{g/cm}^2)} = 0.00123$$

$$\frac{W_{Epoxy}}{X_{0,Epoxy}} = \frac{0.125(\text{g/cc}) \times 39.5(\mu\text{m})}{298.7(\text{mm}) \times 0.125(\text{g/cc})} = 0.00132$$

$$X_0 = W / \left(\frac{W_{Epoxy}}{X_{0,Epoxy}} + \frac{W_{Ag}}{X_{0,Ag}} \right) = \frac{3.2(\text{g/cc}) \times 50\mu\text{m}}{0.00123 + 0.00132} = 1.96\text{cm}$$

Is it correct? (this calcuration was done just before 10min from the talk, so there may be some mistakes.....)